

Observations on Monte Carlo simulations for 2022 Test Beam

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LUXE

Test Beam @ DESY in 2022

Testing New Sensor Prototypes

- Test beam goal:
 - Studies of sensor response of Si and GaAs pad sensors prototype, with up-to-date development of FLAXE FE and FPGA read-out, to electrons with energy in the range of 1 to 5 GeV in the DESY II electron beam
- Simulations goals:
 - replicating various experimental configurations
 - define the primary particle characteristics
 - verify the physics list influence
 - collect quantities of interest (eg. pad hits, energy deposition)
 - cross-check with experimental data
 - *Resolution:* correlate the sensor response to the hit position.
 - *Efficiency:* the sensors should have registered a hit

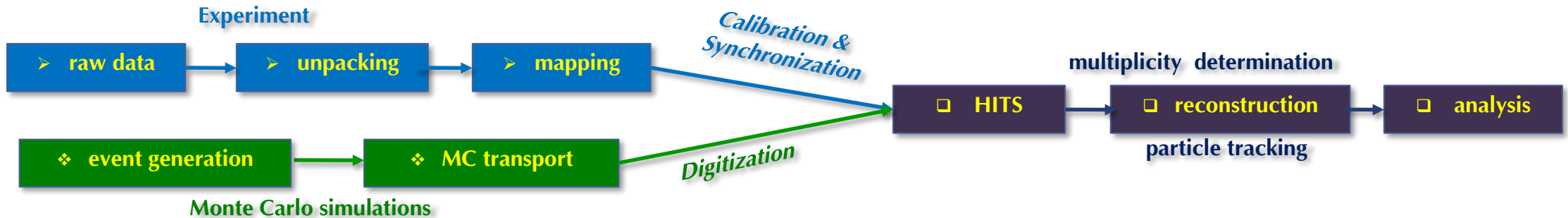
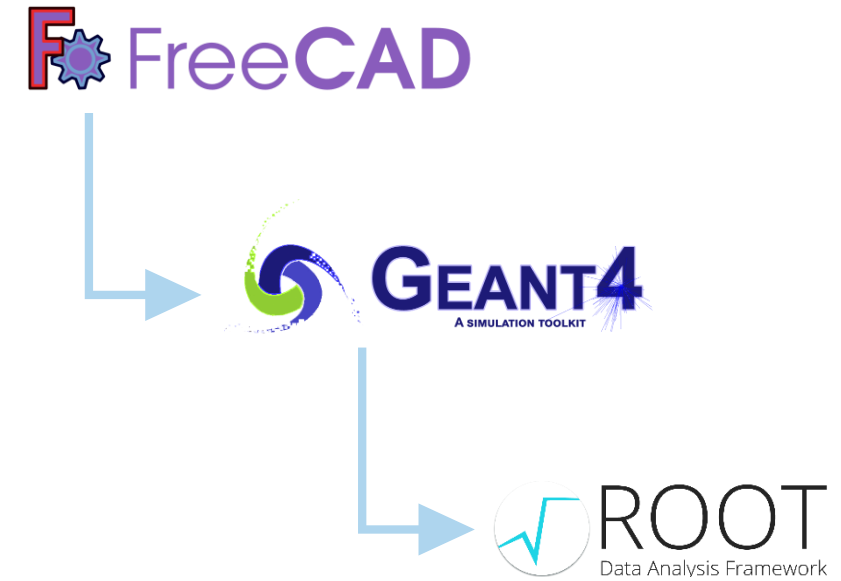


This talk presents the overall simulations.

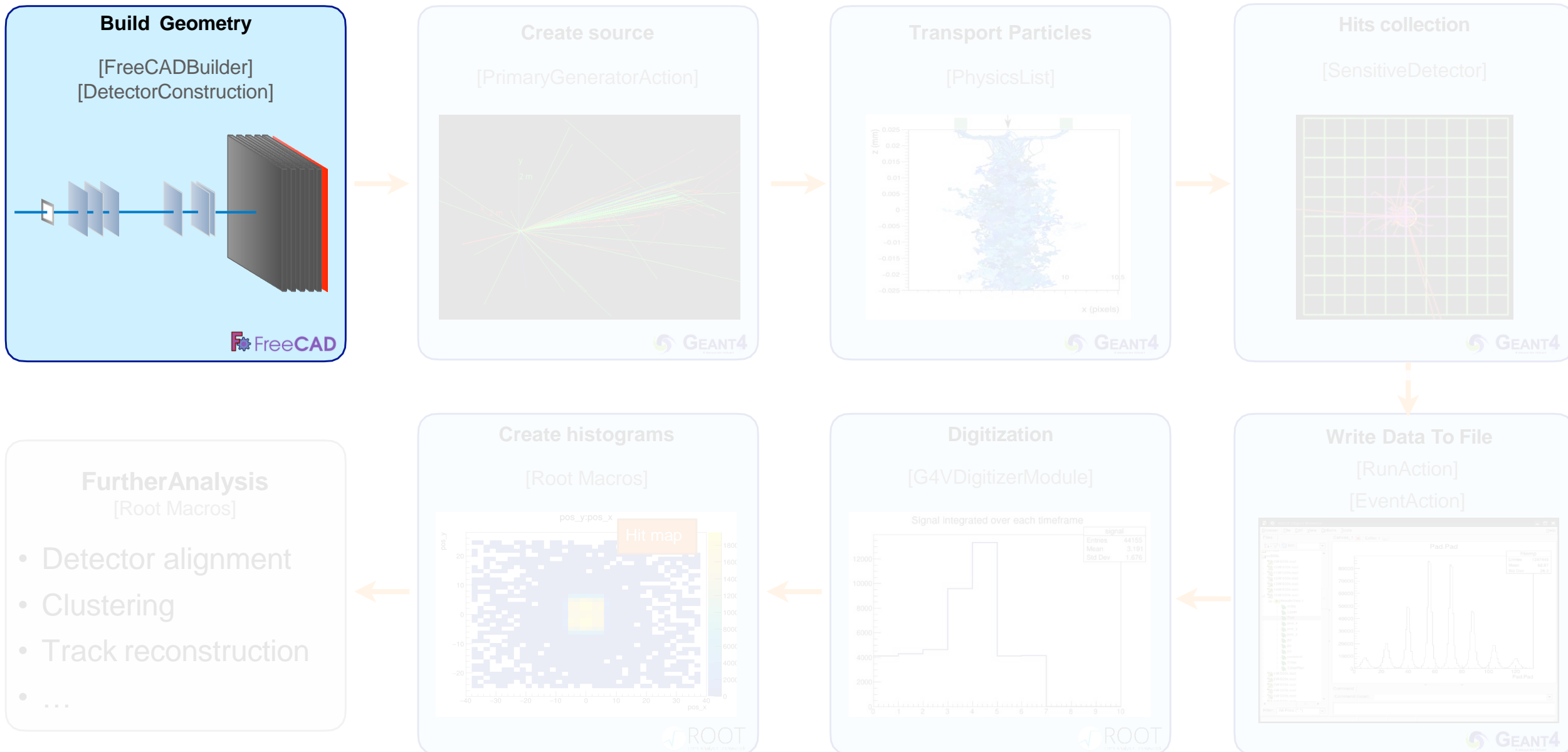
Monte Carlo simulations and data analysis workflow

FreeCAD, Geant4, Root

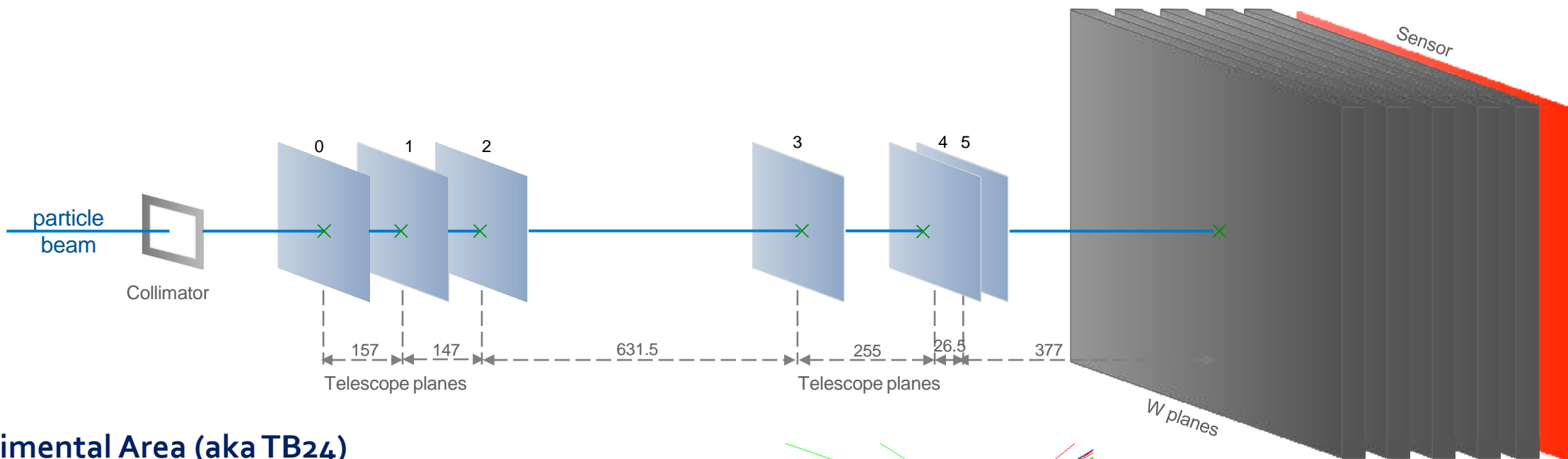
- **30 experimental setups** generated and exported using simple computer-aided design – **FreeCAD**
challenge: export to a format readable by simulation tool
- **full response of the sensor** and the test beam setup with high statistics is simulated with **Geant4.11.06**
challenge: choose/construct physics list, write data to file
- **data analysis** of the test beam sensors is performed using **ROOT** framework
challenge: extract physical quantities matching experimental data



Monte Carlo simulations and data analysis workflow

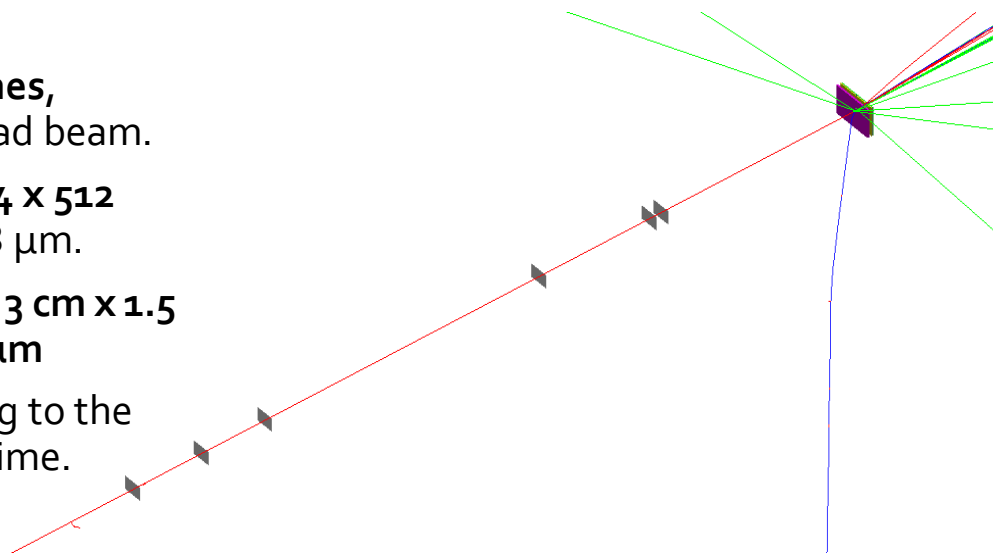


Test beam general setup



Experimental Area (aka TB24)

- **telescope** consist of **6 parallel planes**, perpendicular to a e^- gaussian spread beam.
- each telescope plane consist of **1024 x 512 pixels**, pixel pitch $29.24 \mu\text{m} \times 26.88 \mu\text{m}$.
- the **active area** is roughly of the size **3 cm x 1.5 cm**; the thickness of the chip is **$\sim 50 \mu\text{m}$**
- telescope planes **position** according to the **real measurements** during beam time.



TestBeam box frame

- **sensors enclosure** is simulated as a box with an **Al foil** for entrance window.
- **W plates** with various compositions/thickness
- sensors of various types (3 Si & 2 GaAs)
- **each geometry object** is checked for **misalignment** and an **alignment correction** for position and orientation is included.

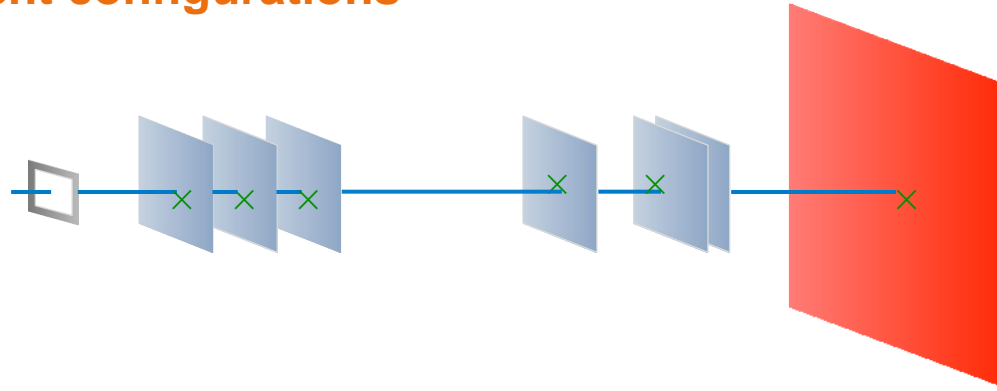
Test Beam configurations

10 setups - 38 different configurations

■ Ga-As sensor – Anton1

1 setup only with sensor

Energies: 5 GeV



■ Si sensor – C72

1 setups only with sensor

Energies: 5 GeV

■ Ga-As sensor – Yan1

1 setup only sensor

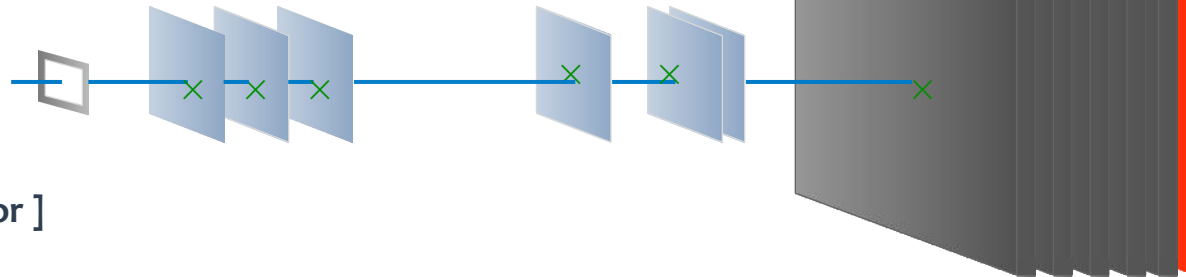
Energies: 5 GeV

1 setup [5 W plates + sensor]

Energies: 1 GeV, 3 GeV, 5 GeV

1 setup [15 -> 1 W plates + sensor]

Energies: 5 GeV



■ Si sensor – C74

1 setup only with sensor

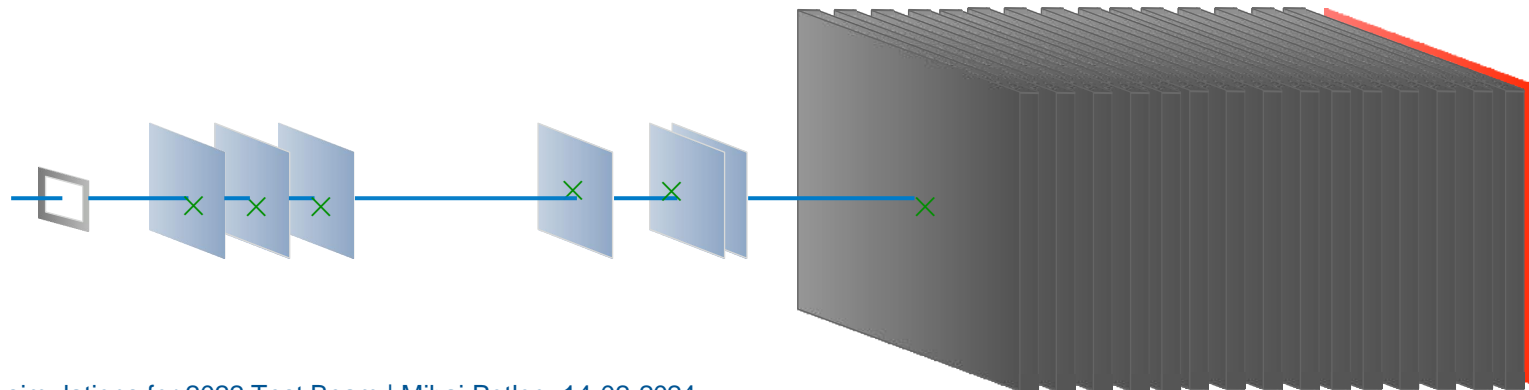
Energies: 5 GeV

1 setup [5 W plates + sensor]

Energies: 1 GeV, 3 GeV, 5 GeV

1 setup [15 -> 1 W plates + sensor]

Energies: 5 GeV



■ Si sensor – C75

1 setup only with sensor

Energies: 5 GeV

Investigated layouts

sensors, converter

■ Ga-As sensor – Anton1, Yan1 & BeamCal

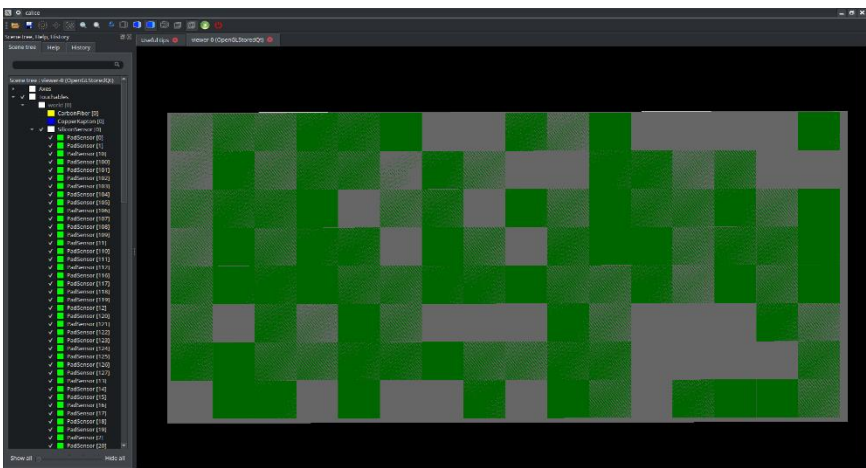
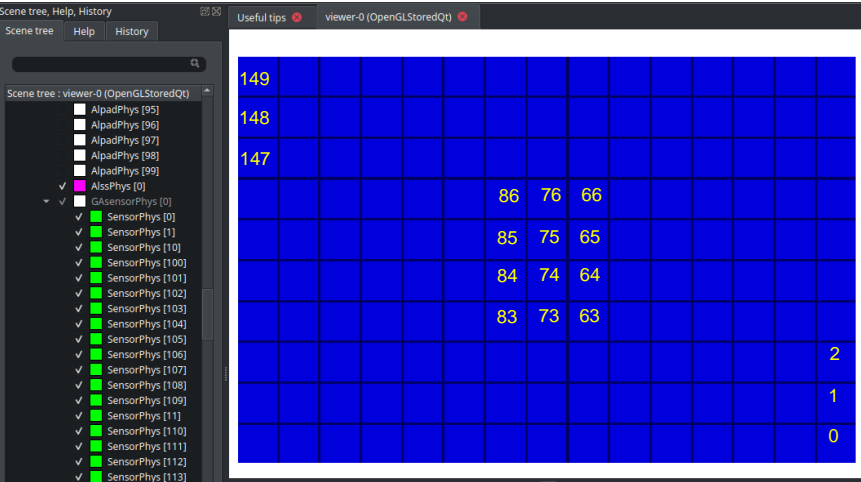
- rectangular shape: 7.47 cm x 4.97 cm
- pad size: 4.7 mm x 4.7 mm
- gap between pads 0.3 mm
- number of pads: 15 x 10
- thickness 500 μ m

■ Si sensor – C72, C74 & C75

- rectangular shape: 9 cm x 4.5 cm
- pad size: 5.5 mm x 5.5 mm
- number of pads: 16 x 8
- thickness: 320 μ m

Tungsten plates

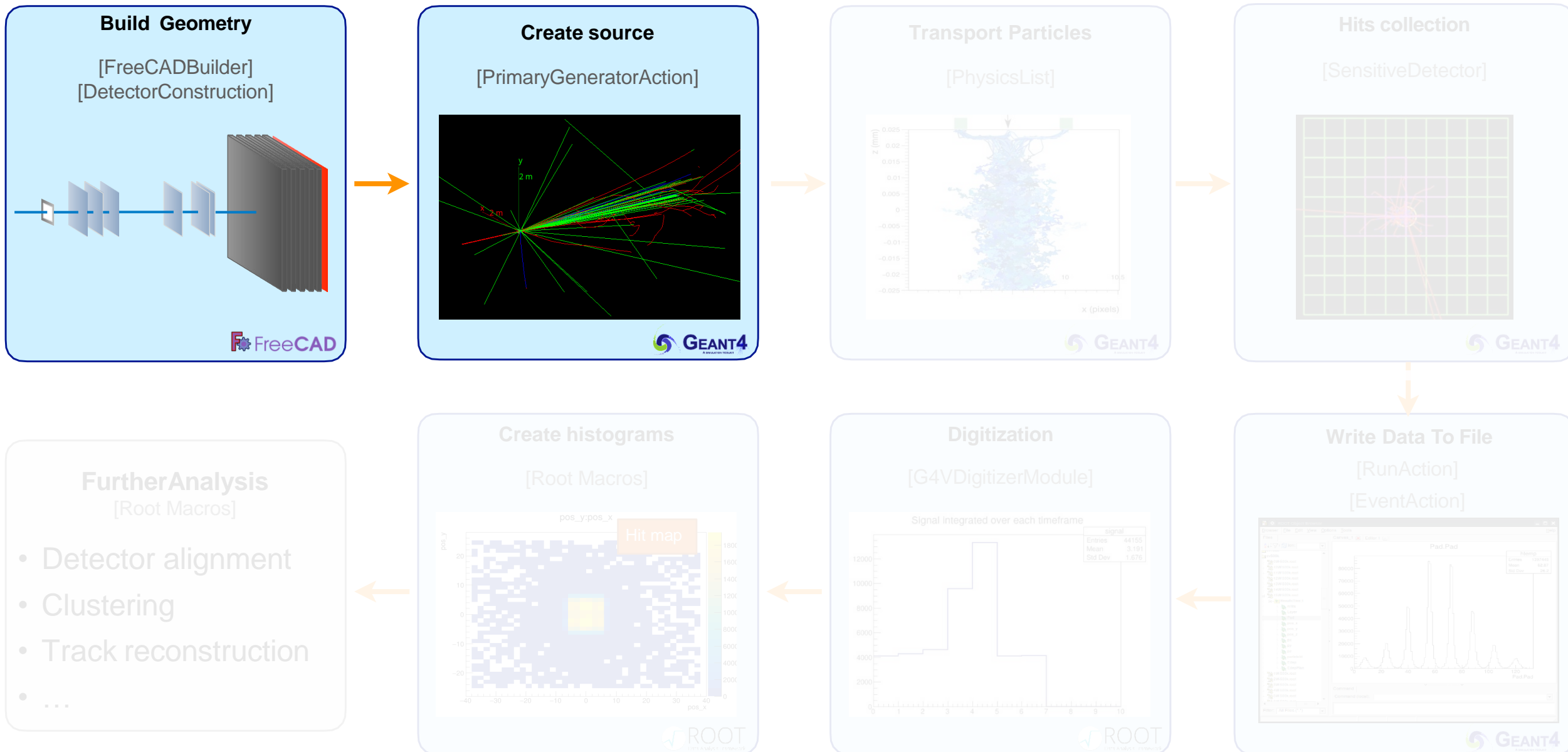
- 2 different compositions:
 - 7 with 93% W
 - 8 with 95% W
- Various thickness:
 - from 3.470 to 3.645 mm



Stack configuration				
V beam V				
Slot 1	Plane "1"	tungsten	3,505	abs95
Slot 2	Plane "3"	tungsten	3,520	abs95
Slot 3	A5	tungsten	3,528	abs95
Slot 4	A2	tungsten	3,550	abs95
Slot 5	Plane "4"	tungsten	3,475	abs95
Slot 6	B12	tungsten	3,550	abs95
Slot 7	A8	tungsten	3,558	abs95
Slot 8	B23	tungsten	3,543	abs95
Slot 9	B21	tungsten		
Slot 10	1 (A3)	tungsten		
Slot 11	B19	tungsten		
Slot 12	B14	tungsten		
Slot 13	7 (MGS2)	tungsten	3,521	abs93
Slot 14	10 (MGS5)	tungsten	3,645	abs93
Slot 15	11 (MGS6)	tungsten	3,470	abs93
Slot 16	---	gap		
Slot 17	Calice 74	sensor		
Slots 18--end	---	empty		

- complete implementation of all type of sensors – Anton1, Yan1, BeamCal, C72, C74, C75
- re-numbered the pads to correspond to channels from real sensors
- macro with commands for easily geometry change

Monte Carlo simulations and data analysis workflow



Primary particle generation

particleGun, GPS

Create 'diverging' beam

- when firing an accelerator based beam, the beam will have some divergence and shape
- 12 x 12 mm² collimator -> square source
- **gaussian energy distribution** with 0.1% spread
- 0.752 mrad **divergence**

particleGun

```
G4int n_particle = 1;
fParticleGun = new G4ParticleGun(n_particle);

G4ParticleTable* particleTable = G4ParticleTable::GetParticleTable();
G4String particleName;
fParticleGun->SetParticleDefinition(particleTable->FindParticle(particleName="e-"));

G4double theta, phi;
G4double px, py, pz;
G4double sigmaAngle = 0.752;
theta = G4RandGauss::shoot(0.0, (sigmaAngle*pi) / 180.);
phi = twopi * G4UniformRand();
px = -std::sin(theta) * std::cos(phi);
py = -std::sin(theta) * std::sin(phi);
pz = -std::cos(theta);
fParticleGun->SetParticleMomentumDirection(G4ThreeVector(px, py, pz));
G4double zur = -3270.0*mm, x = 18.*mm, y = 12.*mm;
G4double xur = x * (2*G4UniformRand()-1);
G4double yur = y * (2*G4UniformRand()-1);
fParticleGun->SetParticlePosition(G4ThreeVector(xur,yur,zur));

//Energy
G4double beamEnergy = 5000.*MeV;
G4double energySigma = 0.01;
G4double finalEnergy = G4RandGauss::shoot(beamEnergy, beamEnergy*energySigma);
fParticleGun->SetParticleEnergy(finalEnergy);
fParticleGun->GeneratePrimaryVertex(anEvent);
```

GPS

```
/control/verbose 1
/run/verbose 1
/run/initialize

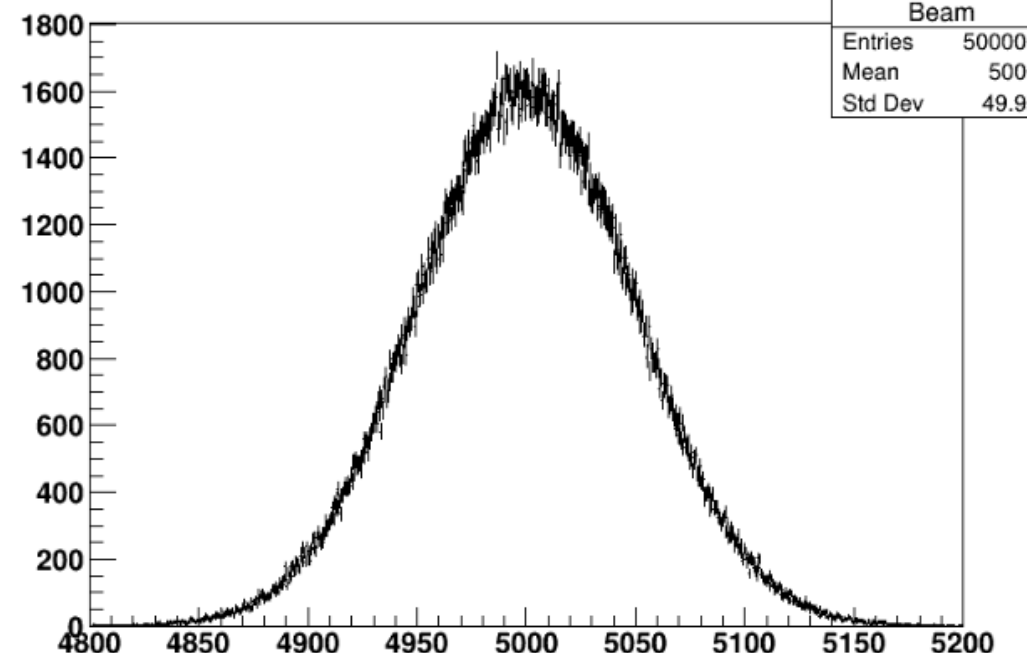
/gps/particle e- // primary particle type

/gps/pos/type Beam
/gps/pos/shape Rectangle // reproduce collimator
/gps/pos/halfx 0.6 cm // 12 mm
/gps/pos/halfy 0.6 cm // 12 mm
/gps/pos/centre 0. 0. -200. cm // distance to sensor position
/gps/direction 0 0 1

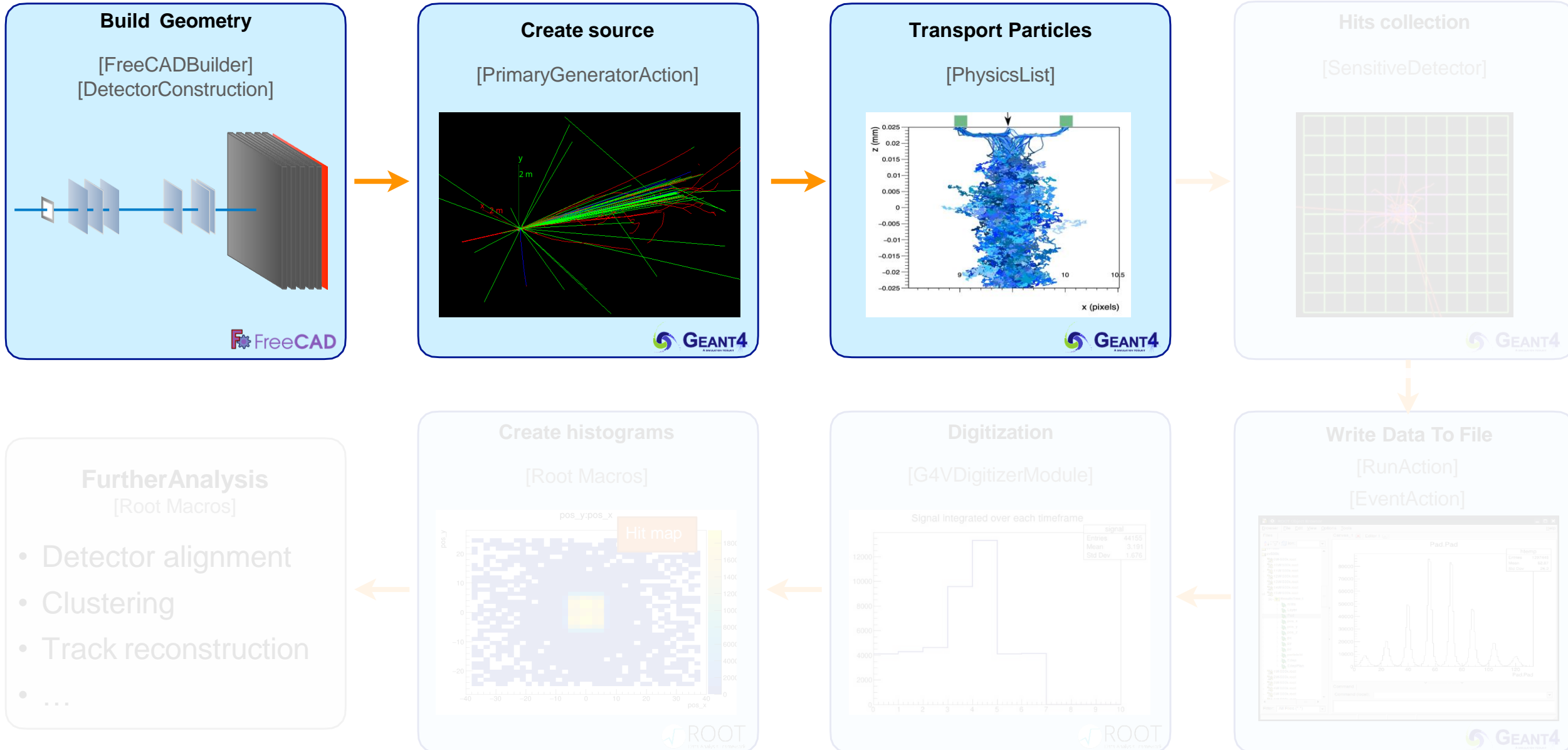
/gps/ene/type Gauss // gaussian distribution
/gps/ene/mono 5000. MeV // beam energy
/gps/ene/sigma 50. MeV // beam energy spread
/gps/ang/sigma_r 0.752 deg // divergence

/run/beamOn 5 // number of events
```

Beam Energy



Monte Carlo simulations and data analysis workflow



G4VUserPhysicsListPhysics, G4VModularPhysicsList

Name of most physics list follows name of physics constructor for hadronic inelastic, optionally followed by EM option

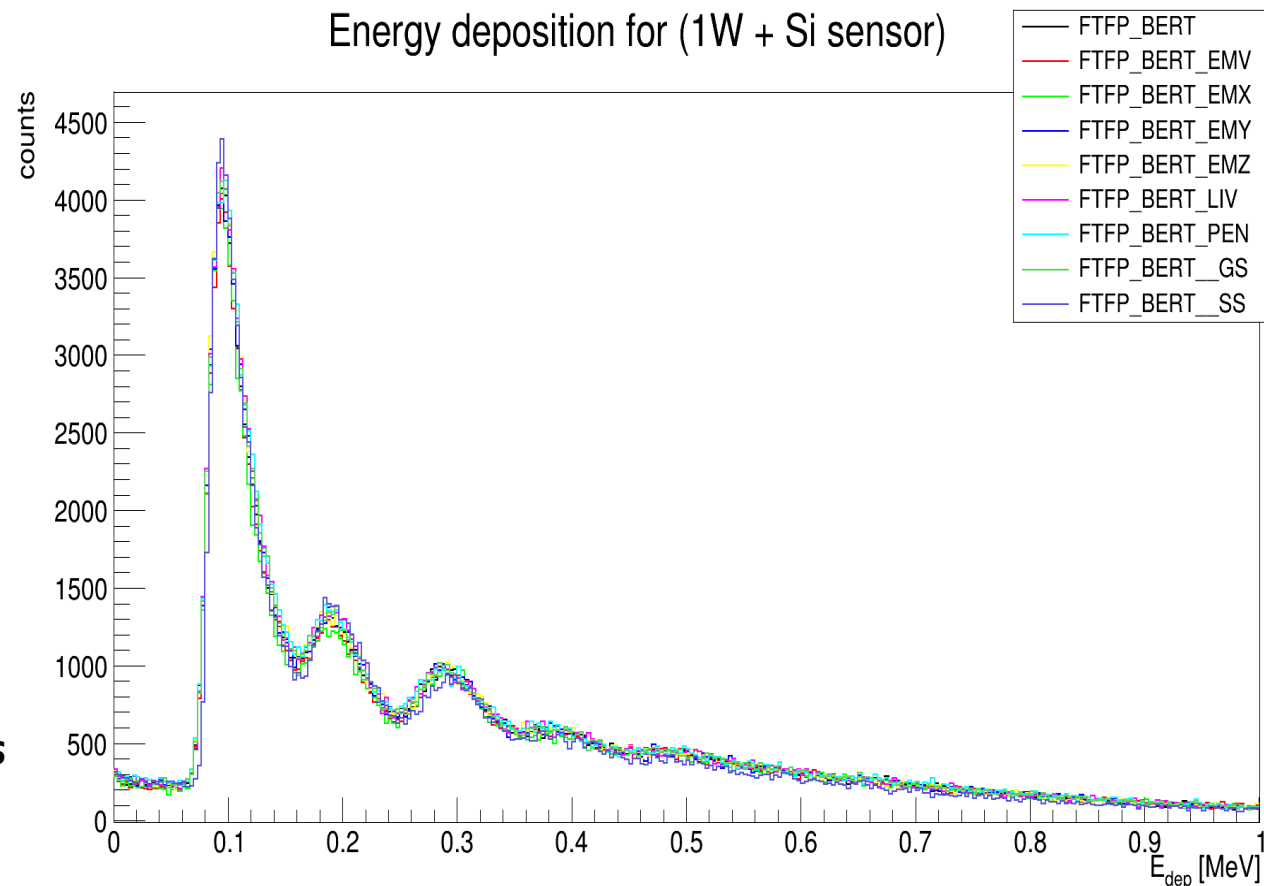
• Name of this hadronic physics constructor indicates models in use from high to low energies

- High energy /string model: **QGS** or **FTF**, used above few (tens) of GeV
 - Extension **P** in **QGSP**/**FTFP**: Precompound & De-excitation model used to de-excite remnant nucleus
- Intermediate energies: **BERT**, **BIC**, **INCLXX**, used up to O(10) GeV
- Low energy neutron/particle transport: **HP**,
- Various shortcuts to indicate special variants, like **TRV** or **LEND**

• Option of electromagnetic physics:

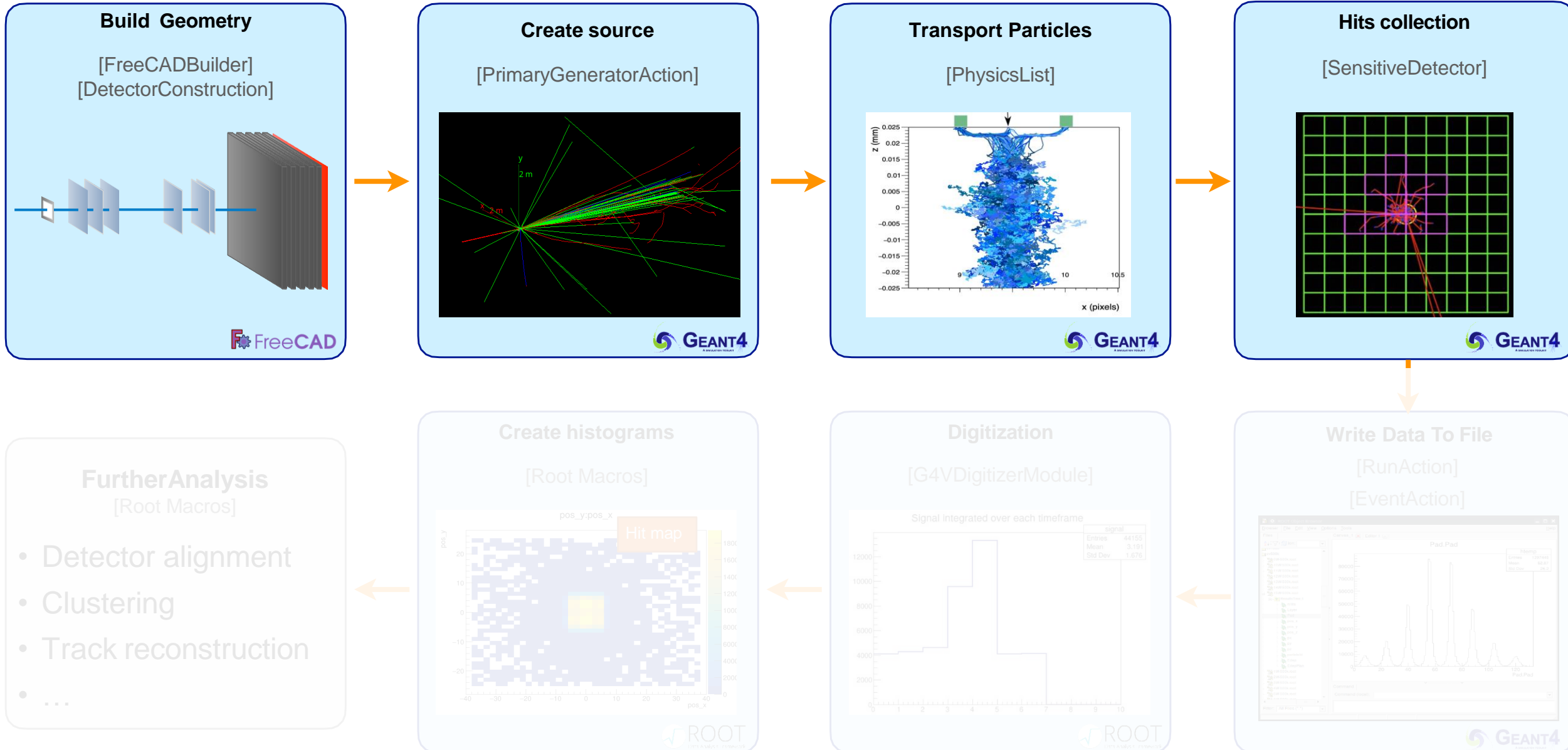
- **EMV** – use Opt1 EM physics
- **EMX** – use Opt2 EM physics
- **EMY** – use Opt3 EM physics
- **EMZ** – use Opt4 EM physics
- plus specific **DNA**, **GS**, **Liv**, **Pen**, **LE**, **WVI**, **SS**

• Exceptions to naming scheme are **Shielding**, **LBE**, and **NuBeam** physics lists



- **FTF_BIC**
- **FTFP_BERT**
- **FTFP_BERT_HP**
- **FTFP_BERT_TRV**
- **FTFP_BERT_ATL**
- **FTFP_INCLXX**
- **FTFP_INCLXX_HP**
- **FTFP_QGSP_BERT**
- **LBE**
- **NuBeam**
- **QGSP_BERT**
- **QGSP_BERT_HP**
- **QGSP_BIC**
- **QGSP_BIC_HP**
- **QGSP_BIC_AllHP**
- **QGSP_FTFP_BERT**
- **QGSP_INCLXX**
- **QGSP_INCLXX_HP**
- **QGS_BIC**
- **Shielding**
- **ShieldingLEND**

Monte Carlo simulations and data analysis workflow

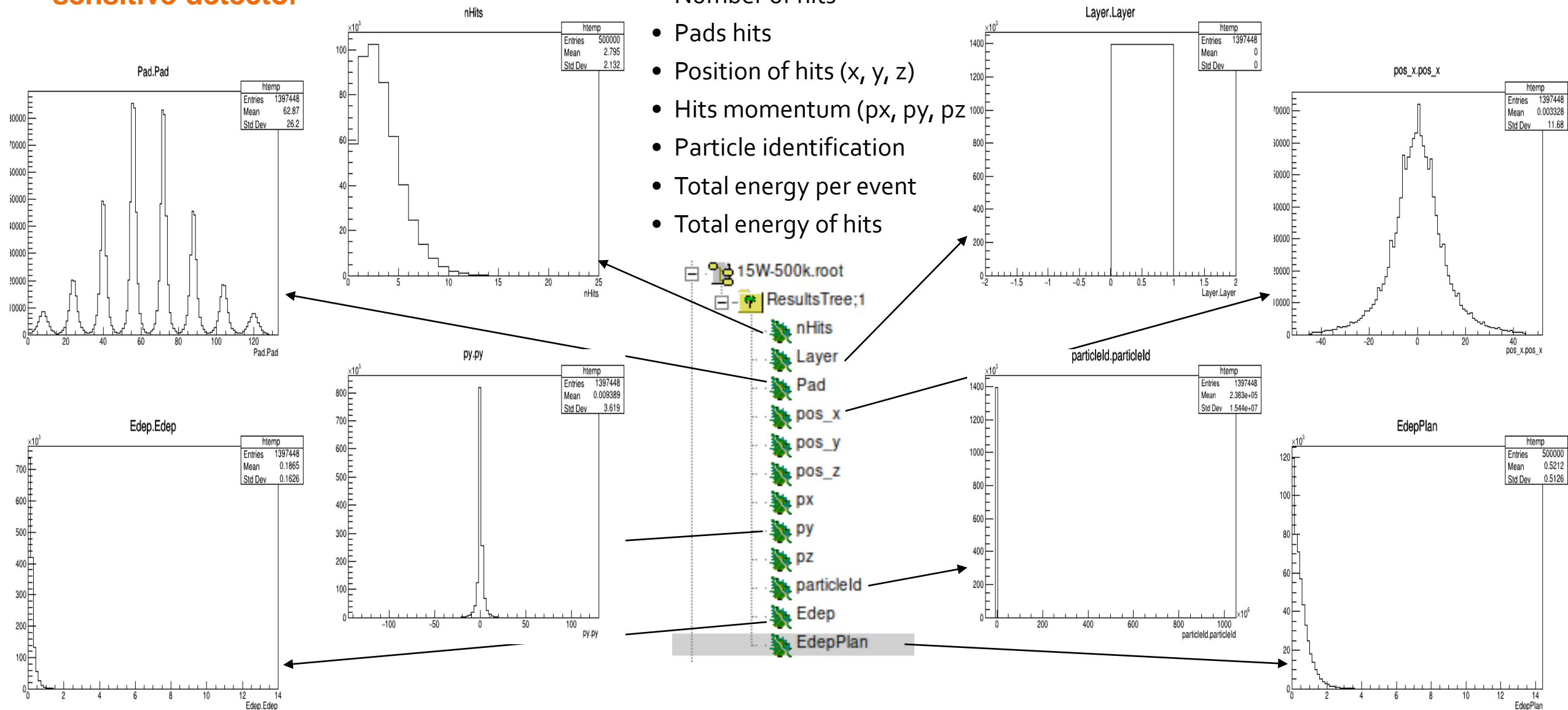


Hits collection

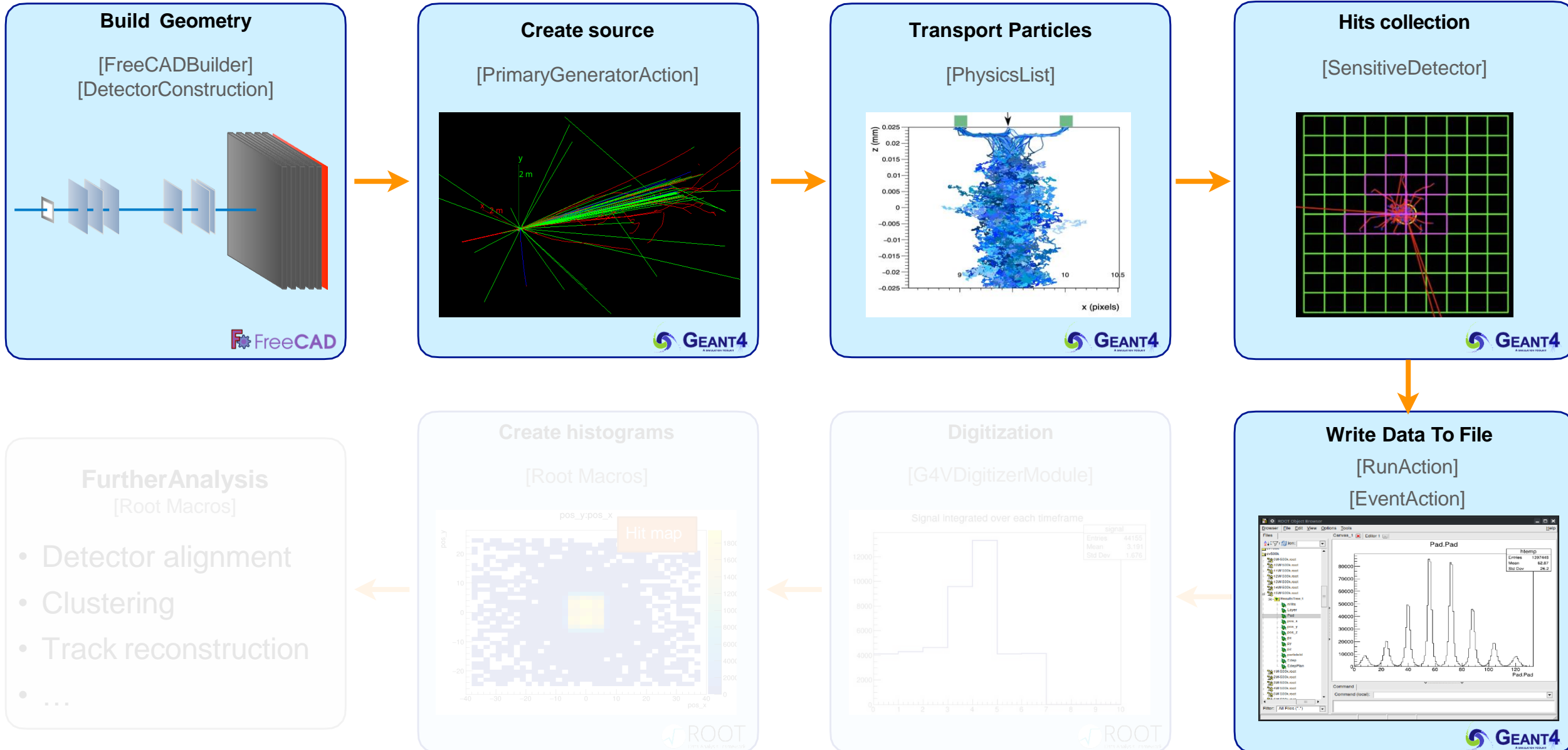
sensitive detector

7 observables

- Number of hits
- Pads hits
- Position of hits (x, y, z)
- Hits momentum (px, py, pz)
- Particle identification
- Total energy per event
- Total energy of hits



Monte Carlo simulations and data analysis workflow



Write data to file

g4root, G4AnalysisManager

RunAction

```
// Default settings
analysisManager->SetVerboseLevel(1);
analysisManager->SetFileName("ecal-luxe.root");

// Creating ntuples
if ( fEventAction ) {
    analysisManager->CreateNtuple("ResultsTree", "Calice simulated data");
    analysisManager->CreateNtupleIColumn("nHits");
    analysisManager->CreateNtupleIColumn("Layer", fEventAction->fCallayer);
    analysisManager->CreateNtupleIColumn("Pad", fEventAction->fCalPad);
    analysisManager->CreateNtupleDColumn("pos_x", fEventAction->fCalX);
    analysisManager->CreateNtupleDColumn("pos_y", fEventAction->fCalY);
    analysisManager->CreateNtupleDColumn("pos_z", fEventAction->fCalZ);
    analysisManager->CreateNtupleDColumn("px", fEventAction->fCalPx);
    analysisManager->CreateNtupleDColumn("py", fEventAction->fCalPy);
    analysisManager->CreateNtupleDColumn("pz", fEventAction->fCalPz);
    analysisManager->CreateNtupleIColumn("particleId", fEventAction->fCalpID);
    analysisManager->CreateNtupleDColumn("Edep", fEventAction->fCalEdep);
    analysisManager->CreateNtupleDColumn("EdepPlan");

    analysisManager->CreateH1("Beam", "Beam Energy", 1000, 4800*MeV, 5200*MeV);
    analysisManager->FinishNtuple();
}
```

EventAction

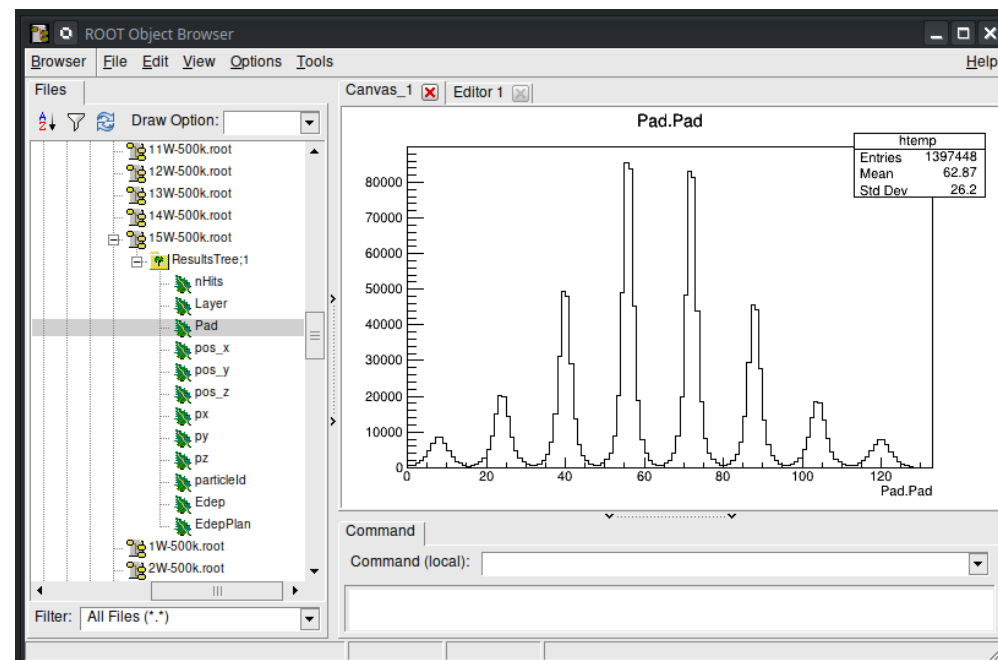
```
for (unsigned long i = 0; i < luxeHC->GetSize(); ++i)
{
    auto hit = static_cast<LuxeHit*>(luxeHC->GetHit(i));
    if(hit->fEdep <= 0.) continue;
    hitsNb++;

    fCallayer.push_back(hit->fLayer);
    fCalPad.push_back(hit->fPad);
    fCalX.push_back(hit->fX);
    fCalY.push_back(hit->fY);
    fCalZ.push_back(hit->fZ);
    fCalPx.push_back(hit->fPx);
    fCalPy.push_back(hit->fPy);
    fCalPz.push_back(hit->fPz);
    fCalpID.push_back(hit->fpID);
    fCalEdep.push_back(hit->fEdep);
    Edepo += hit->fEdep;
}

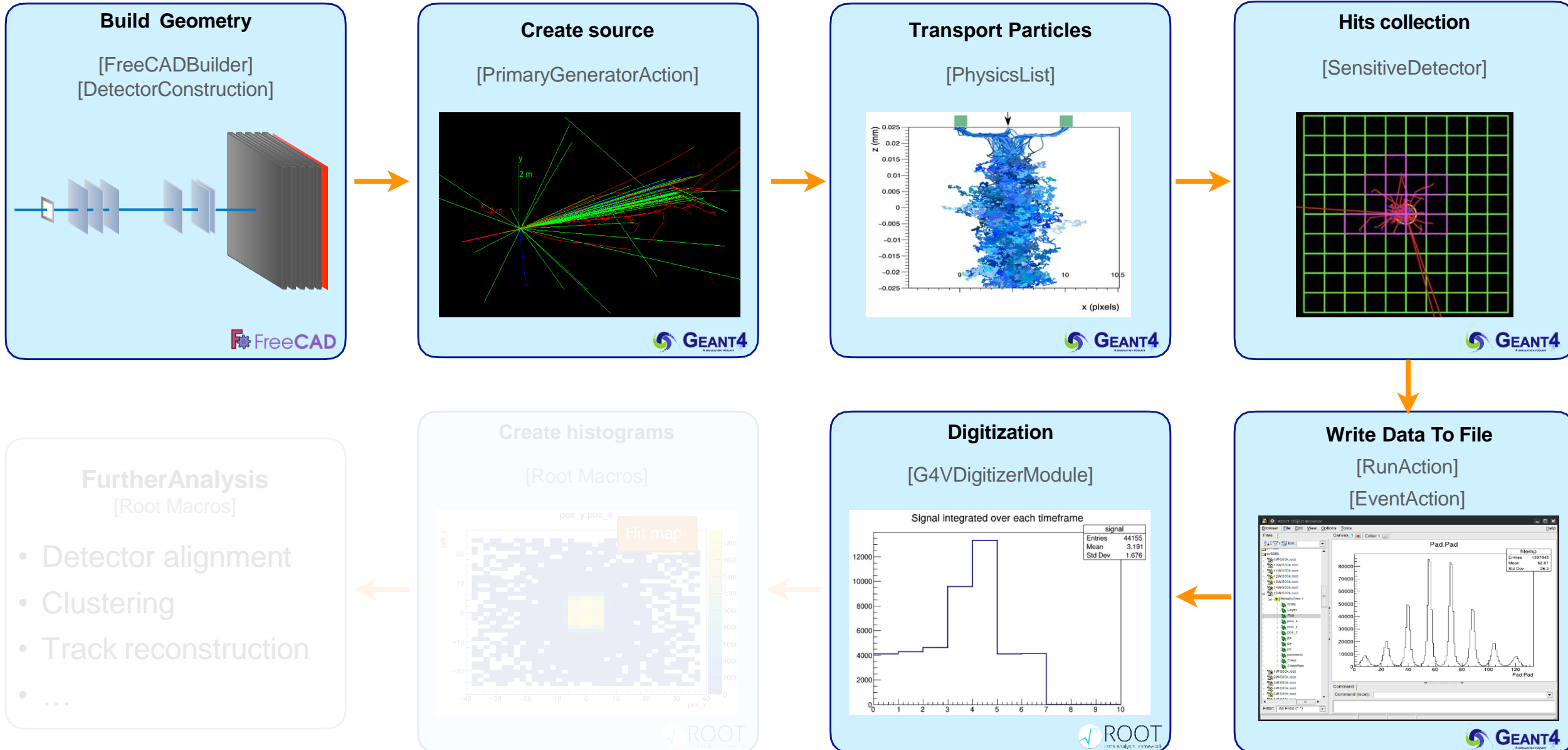
analysisManager->FillNtupleIColumn(0, hitsNb);
analysisManager->FillNtupleDColumn(11, Edepo);

G4double temp=event->GetPrimaryVertex()->GetPrimary()->GetKineticEnergy();
analysisManager->FillH1(0,temp);

analysisManager->AddNtupleRow();
```



Monte Carlo simulations and data analysis workflow



Hits versus digits

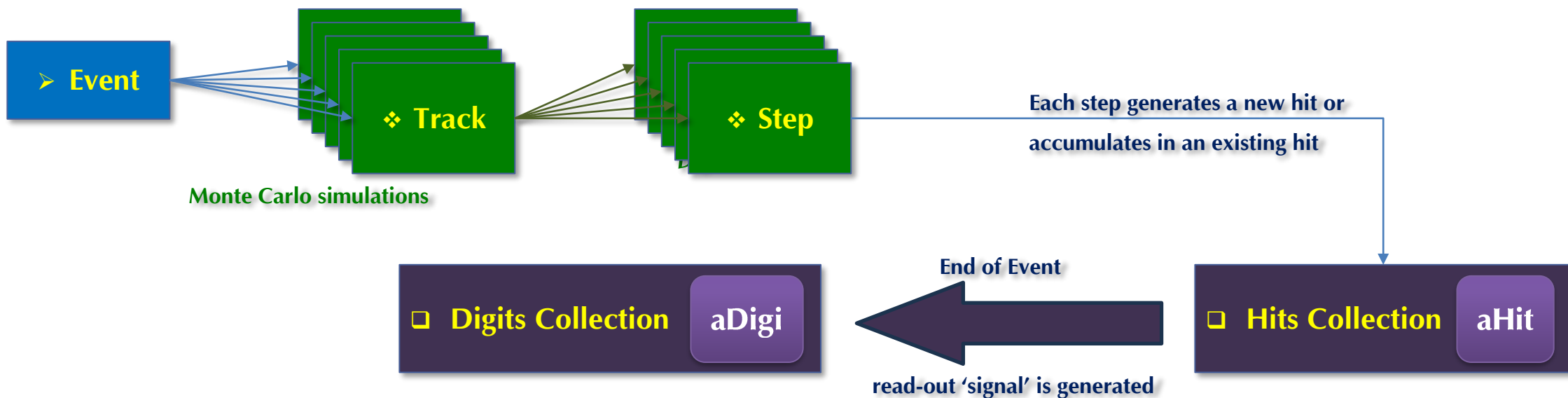
sensitiveDetector, DigitizerModule

G4VHit

- **Hits** are a “snapshot” of the physical interaction of a track (step) or an accumulation of interactions of tracks in the sensitive region of the detector, thus hits represent the “true” energy deposited in the detector

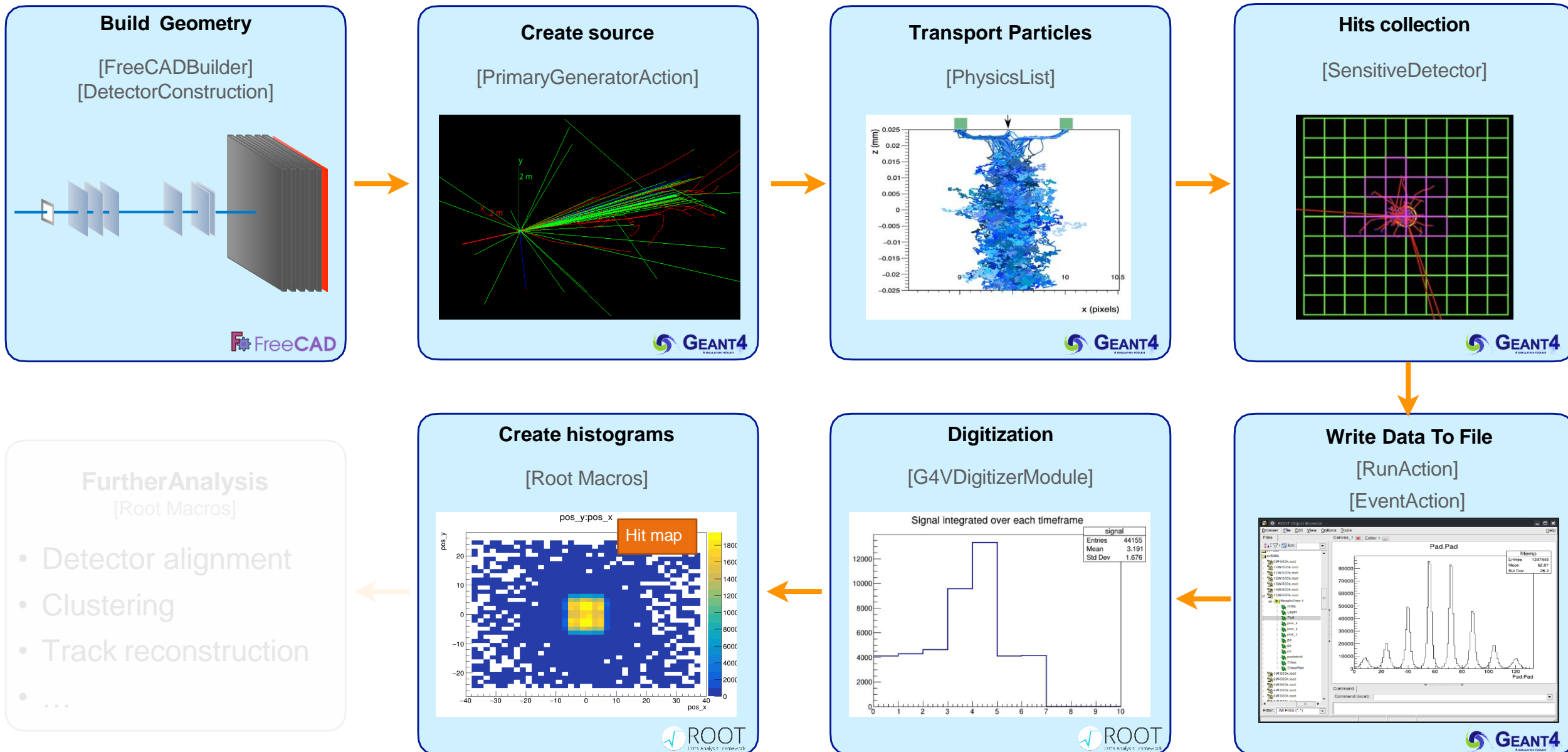
G4VDigitizerModule

- **Digits** are instead intended to be used to simulate the process of reading-out of the signal: for example “true” energy is transformed into collected charge, electronic noise can be applied together with all instrumental effects



No digitization has been applied to simulations performed for this task

Monte Carlo simulations and data analysis workflow

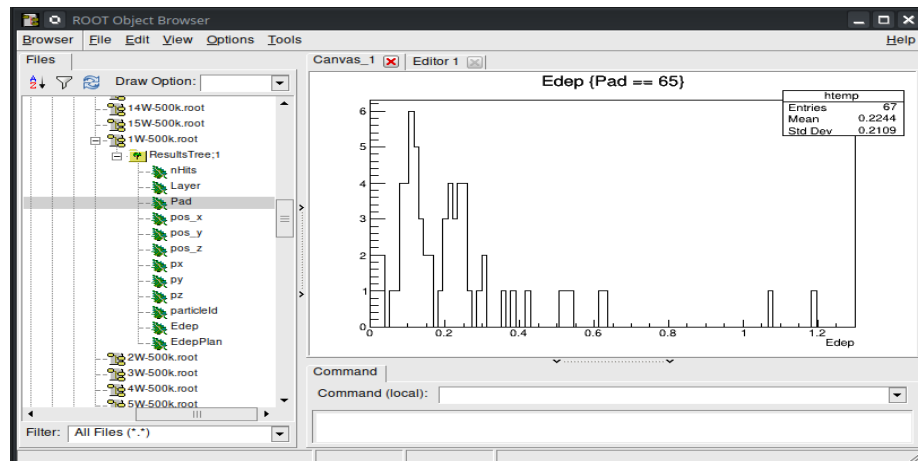


Plotting first histograms

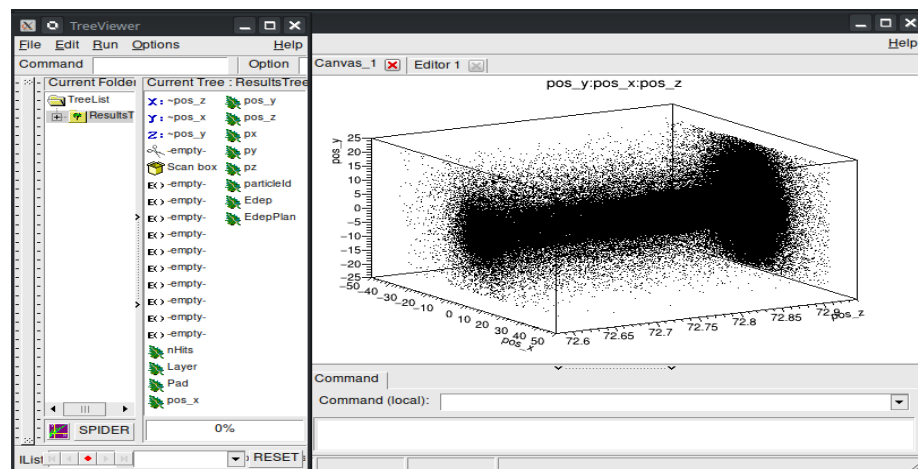
.root commands

Root command

```
root [3] ResultsTree->Draw("Edep", "Pad == 65")
```



StartViewer



Root macros

```
#include "plane.h"

void save_hist_data()
{
    TFile *file2 = new TFile("TB_FIRE_4436.root");
    TTree *tree2 = (TTree*)file2->Get("TreeOnFire");

    TCanvas *c = new TCanvas("c","");

    Int_t nentries2 = (Int_t)tree2->GetEntries();

    Plane *plane[3] {};
    for(int iPlane=0; iPlane < 3; iPlane++) { tree2->SetBranchStatus(Form("Plane_%d",iPlane), &(plane[iPlane])); }

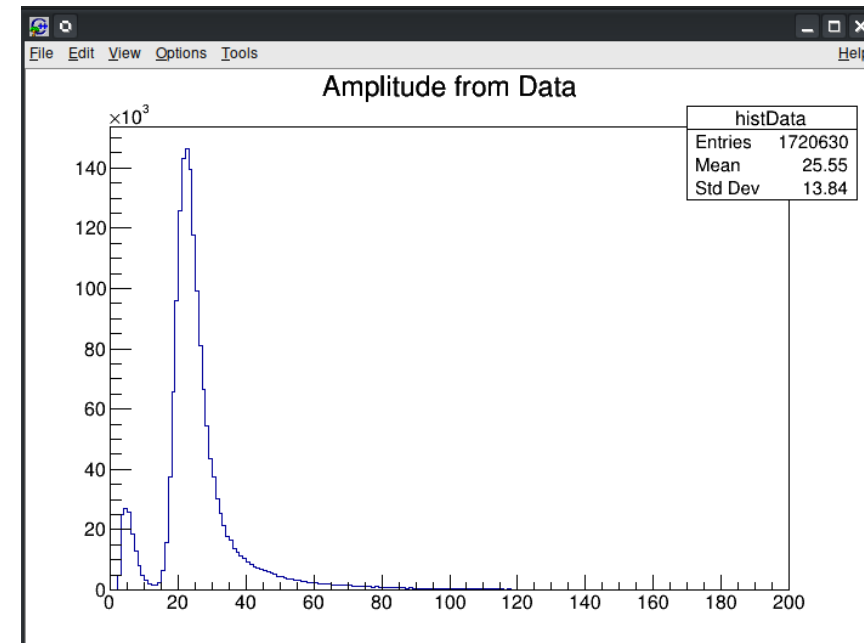
    Plane *planePtr;
    TimeFrame singleTimeFrame;

    TH1F* histData = new TH1F("histData","Amplitude from Data", 200, 0, 200);

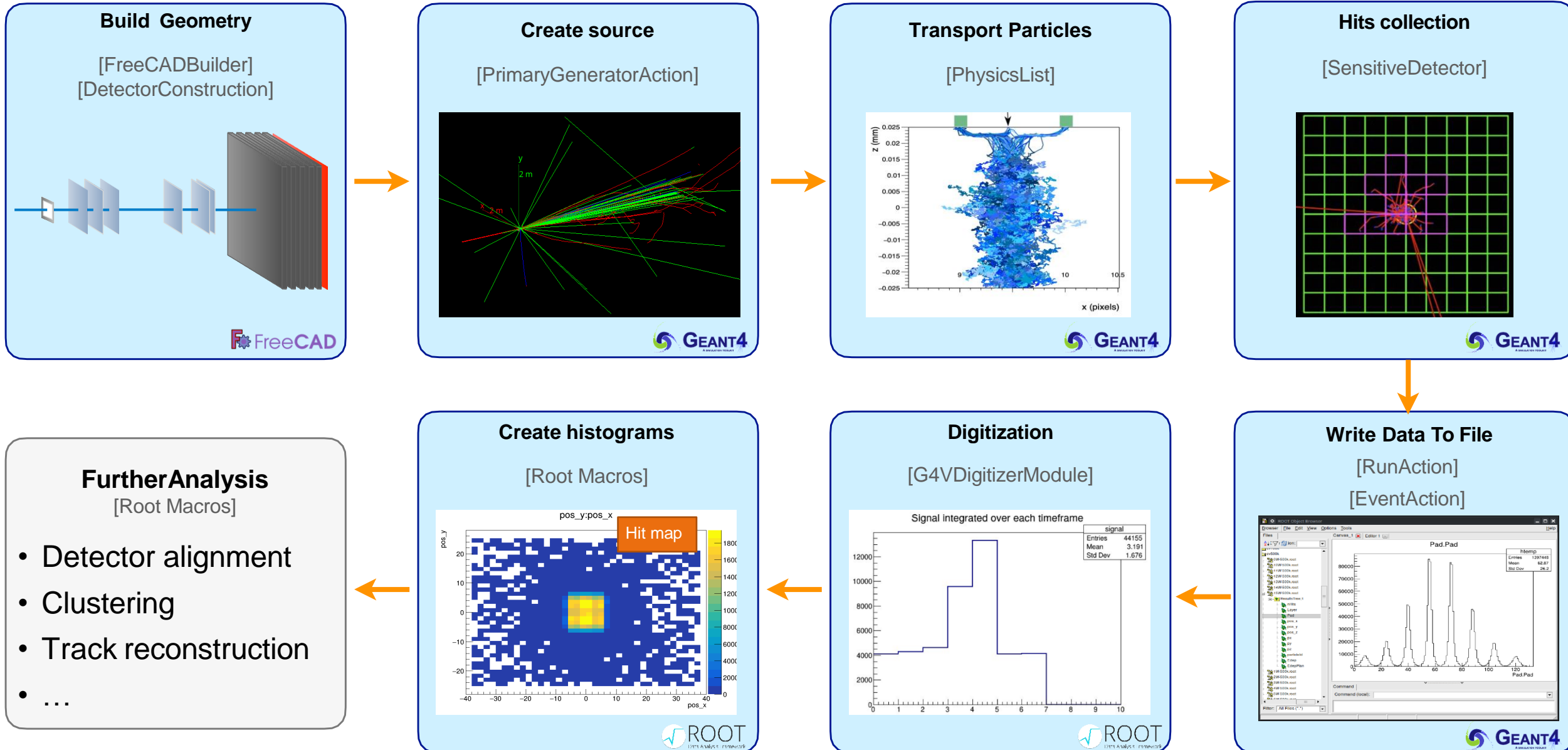
    for (signed int iEvent = 0; iEvent < nentries2 ; iEvent++)
    {
        tree2->GetEntry(iEvent);
        for(signed int iPlane=0; iPlane < 1 ; iPlane++)
        {
            planePtr = plane[iPlane];
            for(unsigned int iTime = 0; iTime < (planePtr->time_frame).size(); iTime++)
            {
                singleTimeFrame = (planePtr->time_frame)[iTime];
                for(int iSample = 0; iSample < singleTimeFrame.nb_of_samples ; iSample++)
                {
                    std::cout << "event:" << iEvent << std::endl;
                    //if( iTime == 3 || iTime == 4) && (singleTimeFrame.amp[iSample] > 10.) && (singleTimeFrame.amp[iSample] < 900.))
                    histData->Fill(singleTimeFrame.amp[iSample]);
                }
            }
        }
    }

    histData->Draw();

    TFile result("histData.root","UPDATE");
    histData->Write();
}
```



Monte Carlo simulations and data analysis workflow



Simulations: Number of e-h pairs created

GaAs sensor – Anton1

Olga Novgorodova's Thesis:

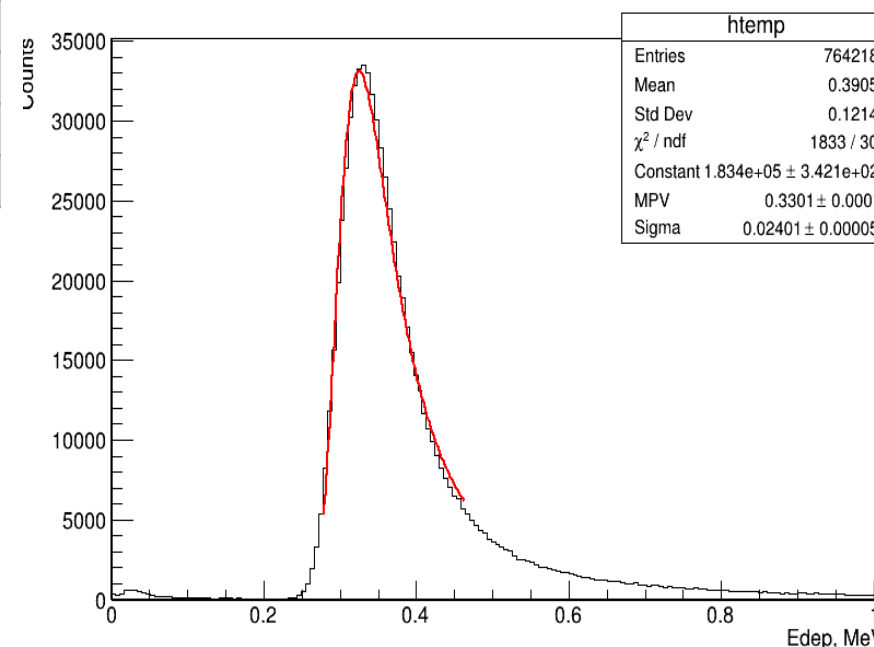
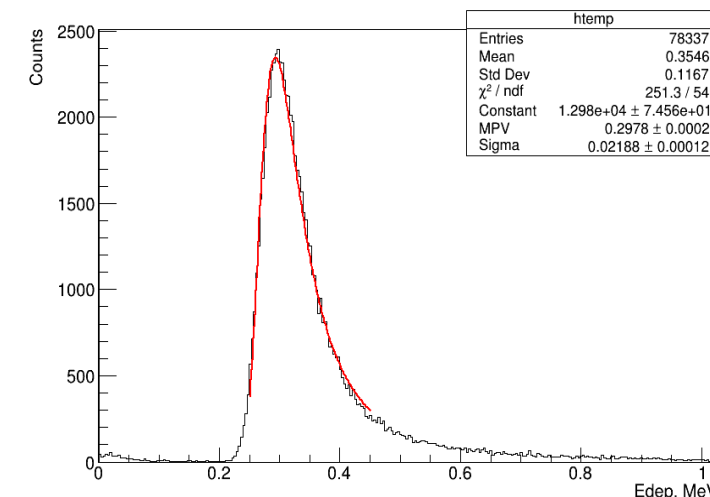
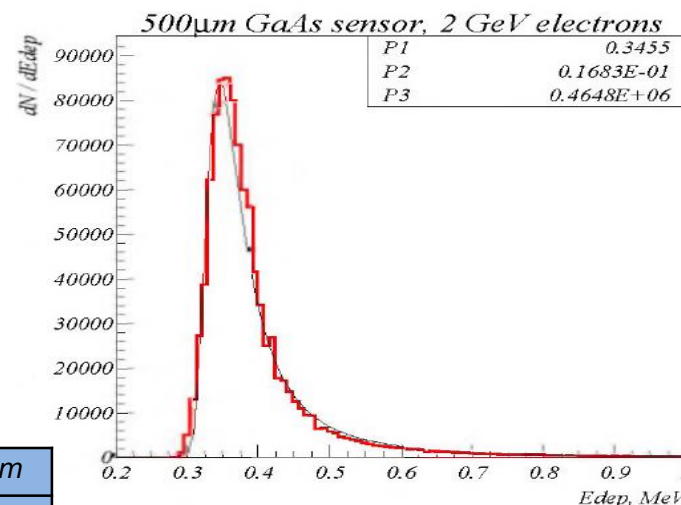
- energy deposition in GaAs sensor
- 500 μm thickness
- ^{90}Sr , and 2, 4 & 4.5 GeV mono-energetic e-
- triggered by 2 / 3 scintillators

Setup	Dep. En. (MeV)	e-h pairs / μm	Dep. En. (MeV)	e-h pairs / μm
^{90}Sr	0.3512	163.4	0.3555	165.34
2 GeV	0.3455	160.7	0.3546	168.86
4 GeV	0.3513	163.4	0.3588	170.86
4.5 GeV	0.3526	164.0	0.3594	171.14
5 GeV			0.3608	171.66

Why differences?

- which are the characteristics of triggers: dimensions, positions, etc.
- Landau fit parameters

Physics list used: FTFP_BERT_EMZ



- Thickness: 550 μm
- $E_{e^-} = 5 \text{ GeV}$
- $E_i = 4.3 \text{ eV}$

Dep. en. (MeV) 0.3905
e-h pairs / μm 165.12

Simulations: Hit map

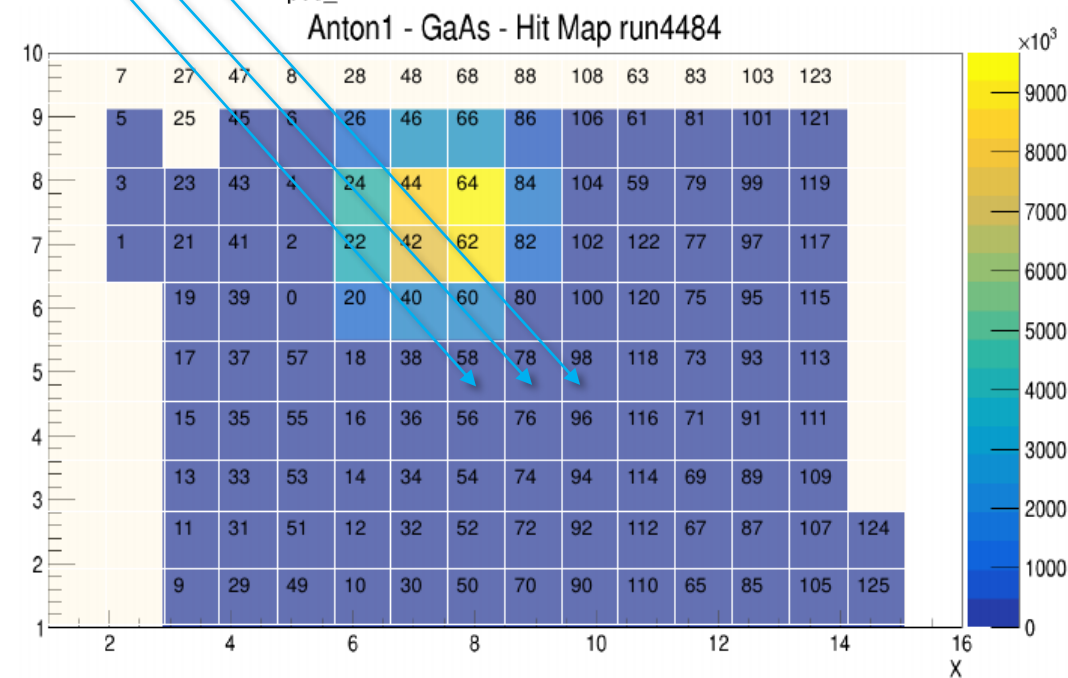
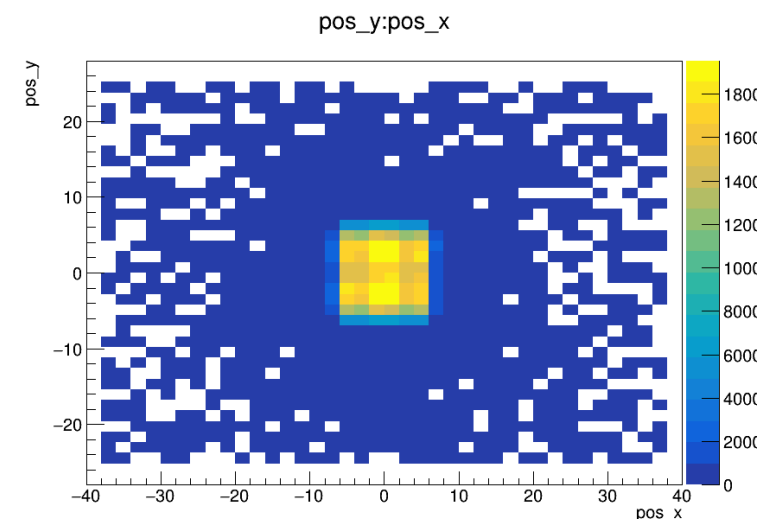
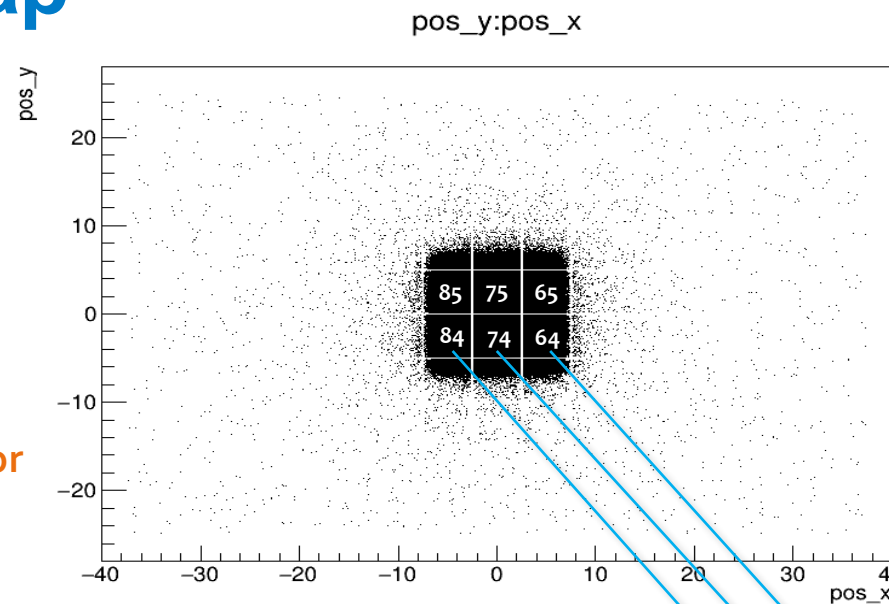
GaAs sensor – Anton1

Hits registered position:

- Primary particle energy: 5GeV
- Number of simulated events: 1 000 000
- Centered on pads 64, 65, 74, 75, 84, 85
- **Converted to channel number from sensor**

Similar with run 4484

	7	27	47	8	28	48	68	88	108	63	83	103	123		
159	149	139	129	119	109	99	89	79	69	59	49	39	29	19	9
	5	25	45	6	26	46	66	86	106	61	81	101	121		
158	148	138	128	118	108	98	88	78	68	58	48	38	28	18	8
	3	23	43	4	24	44	64	84	104	59	79	99	119		
157	147	137	127	117	107	97	87	77	67	57	47	37	27	17	7
	1	21	41	2	22	42	62	82	102	122	77	97	117		
156	146	136	126	116	106	96	86	76	66	56	46	36	26	16	6
	19	39	0	20	40	60	80	100	120	75	95	115			
155	145	135	125	115	105	95	85	75	65	55	45	35	25	15	5
	17	37	57	18	38	58	78	98	118	73	93	113			
154	144	134	124	114	104	94	84	74	64	54	44	34	24	14	4
	15	35	55	16	36	56	76	96	116	71	91	111			
153	143	133	123	113	103	93	83	73	63	53	43	33	23	13	3
	13	33	53	14	34	54	74	94	114	69	89	109			
152	142	132	122	112	102	92	82	72	62	52	42	32	22	12	2
	11	31	51	12	32	52	72	92	112	67	87	107	124		
151	141	131	121	111	101	91	81	71	61	51	41	31	21	11	1
	9	29	49	10	30	50	70	90	110	65	85	105	125		
150	140	130	120	110	100	90	80	70	60	50	40	30	20	10	0



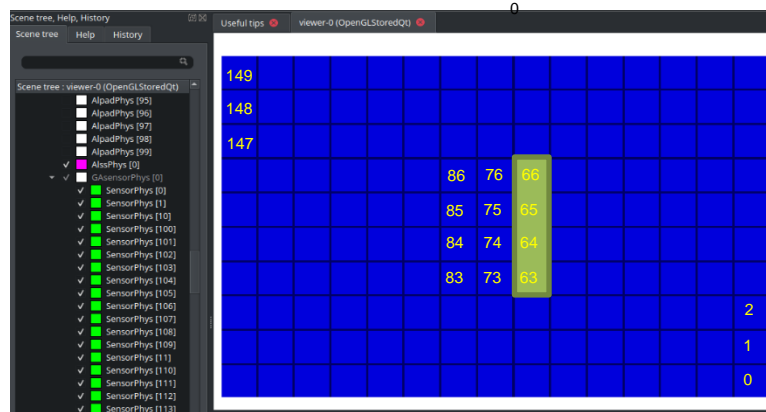
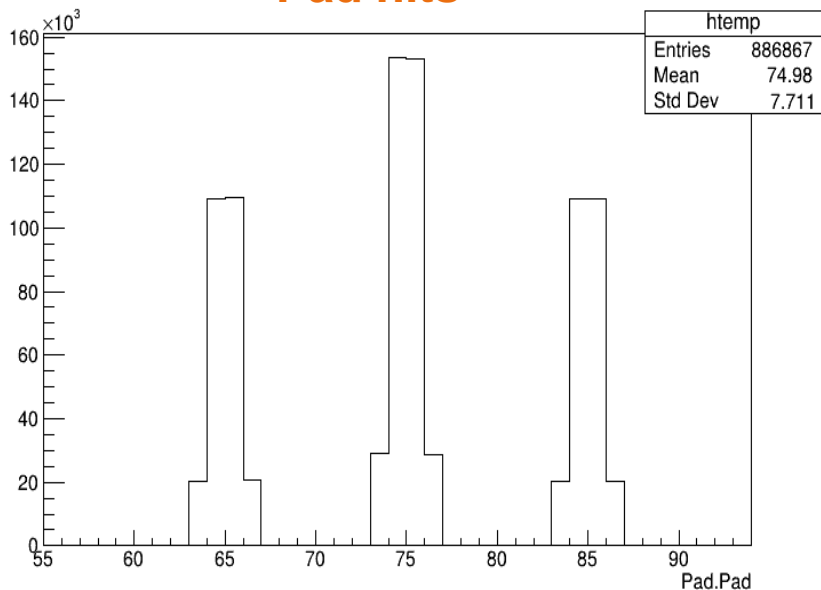
Simulations: Pad Hits

GaAs sensor – Anton1

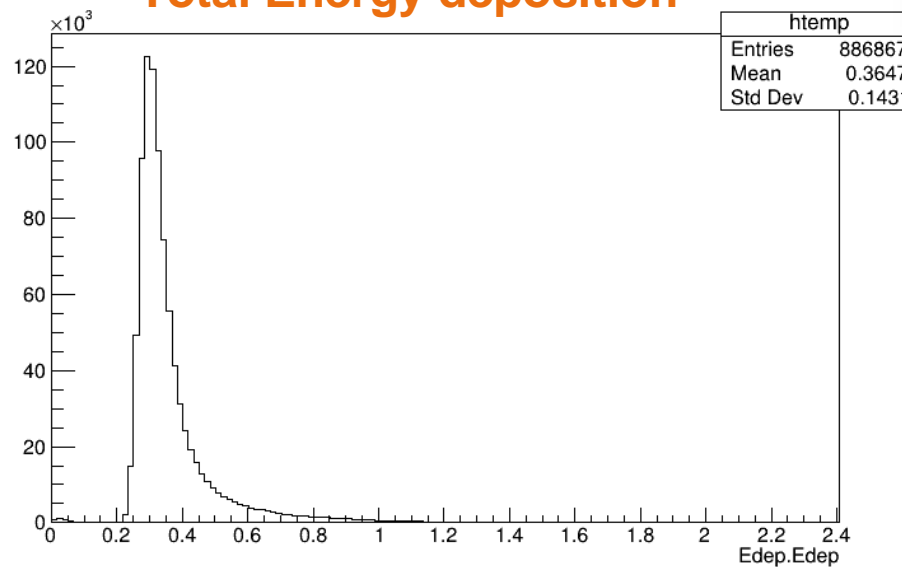
Hits registered position:

- Primary particle energy: 5GeV
- Number of simulated events: 1 000 000
- Centered on pads 64, 65, 74, 75 , 84, 85
- **Converted to channel number from sensor**

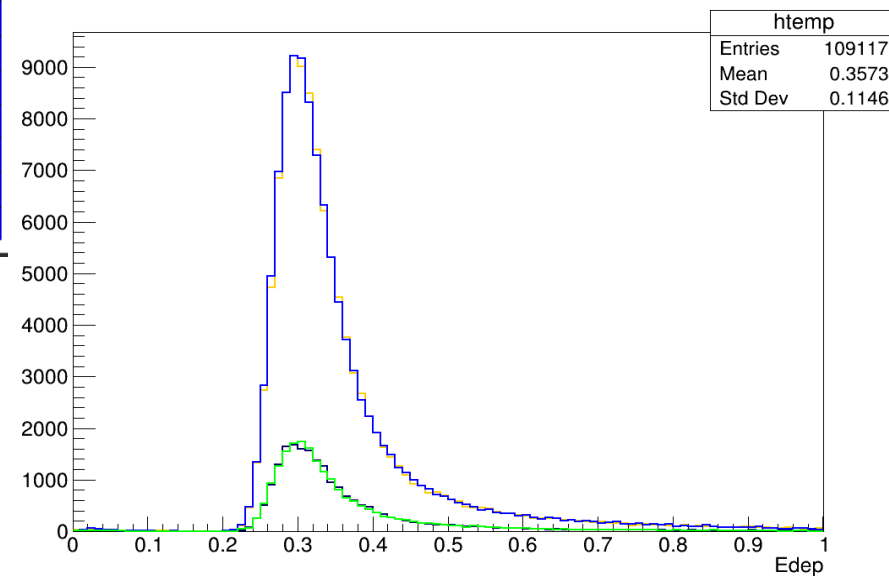
Pad hits



Total Energy deposition



Energy deposition in central pads

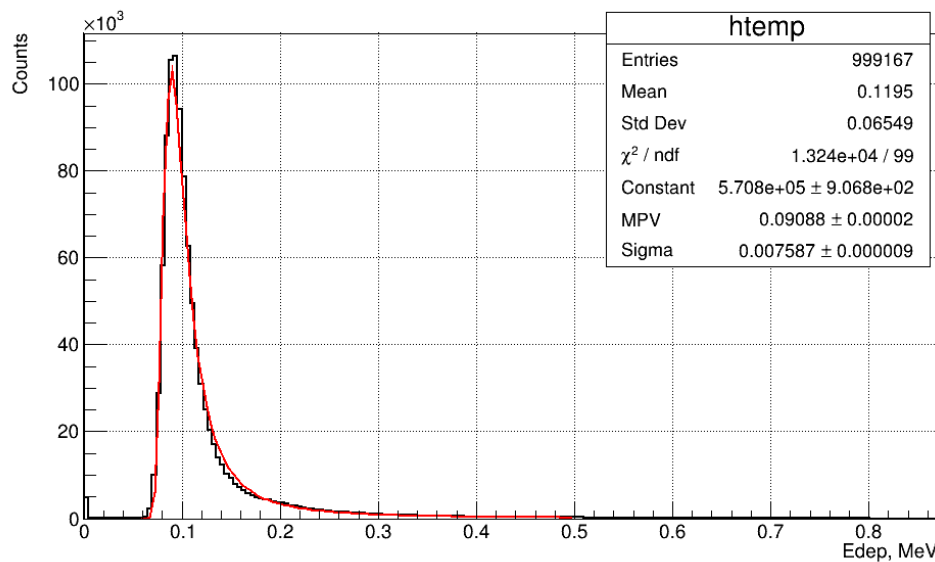


Simulations: Number of e-h pairs created

Si sensor C74 & others

Energy deposition:

- 320 μm thickness
- 5 GeV mono-energetic e-
- triggered by 3 scintillators

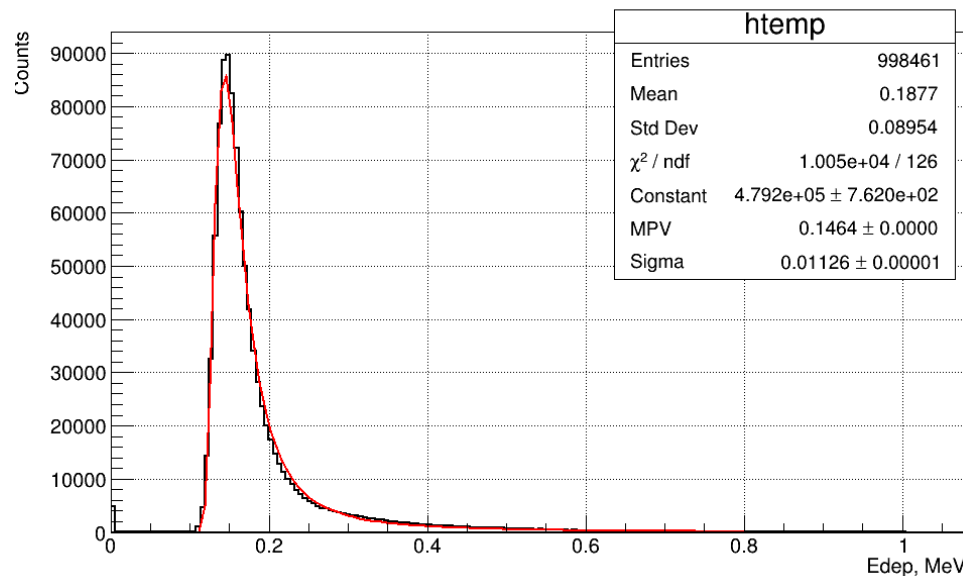


- Thickness: 320 μm
- $E_{e^-} = 5 \text{ GeV}$
- $E_i = 3.62 \text{ eV}$

78.45 e-h pairs per μm

Energy deposition:

- 500 μm thickness
- 3 GeV mono-energetic e-
- triggered by 3 scintillators



- Thickness: 500 μm
- $E_{e^-} = 3 \text{ GeV}$
- $E_i = 3.62 \text{ eV}$

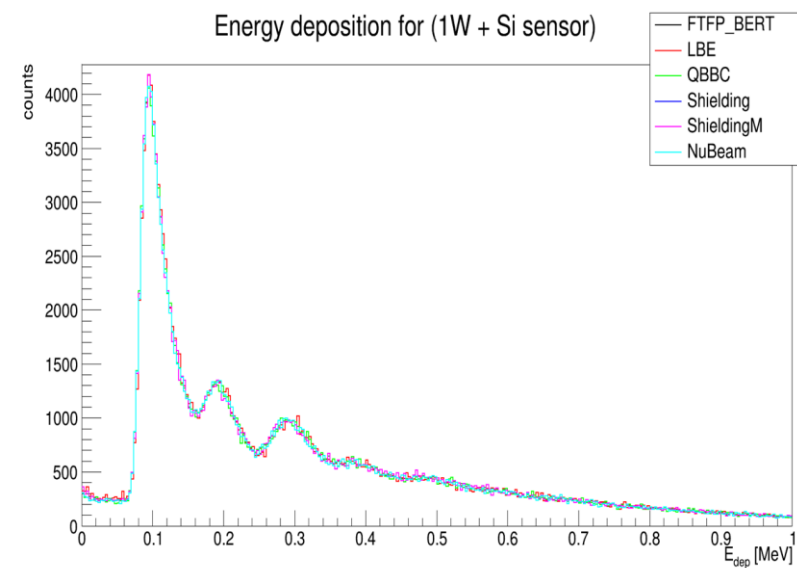
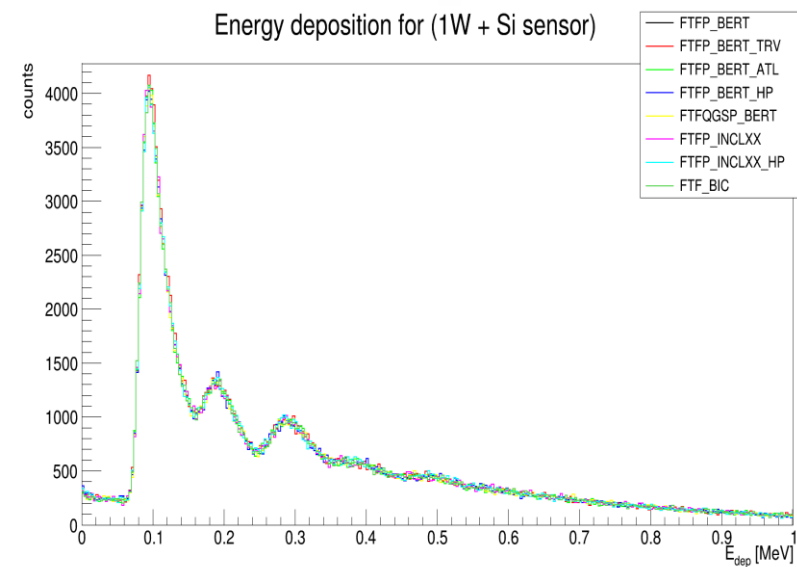
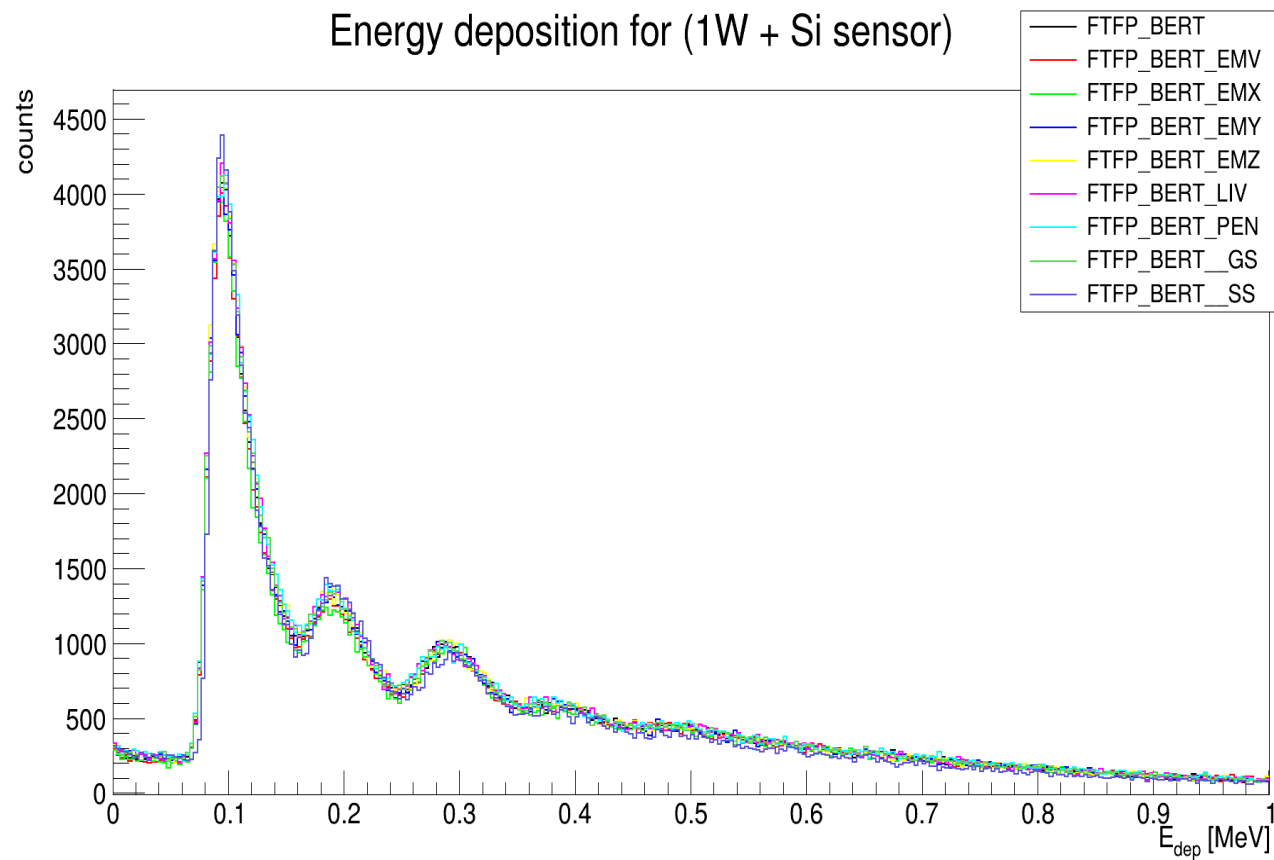
80.88 e-h pairs per μm

Physics list used: **FTFP_BERT_EMZ**

Simulations: Physics list comparison

Si sensor: W + C74

- FTF_BIC
- FTFP_BERT
- FTFP_BERT_HP
- FTFP_BERT_TRV
- FTFP_BERT_ATL
- FTFP_INCLXX
- FTFP_INCLXX_HP
- FTFP_QGSP_BERT
- LBE
- NuBeam
- QGSP_BERT
- QGSP_BERT_HP
- QGSP_BIC
- QGSP_BIC_HP
- QGSP_BIC_AllHP
- QGSP_FTFP_BERT
- QGSP_INCLXX
- QGSP_INCLXX_HP
- QGS_BIC
- Shielding
- ShieldingLEND



Simulations: MeV to ADC

GaAs sensor – Anton1

Energy deposition:

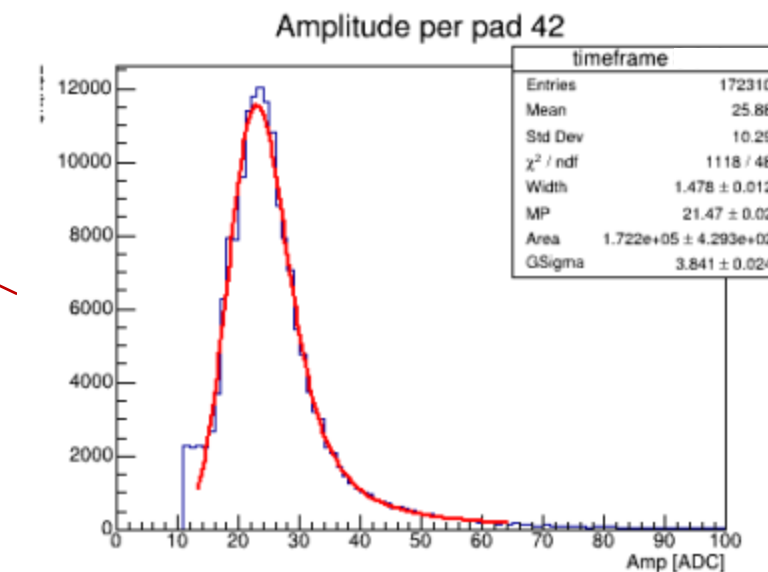
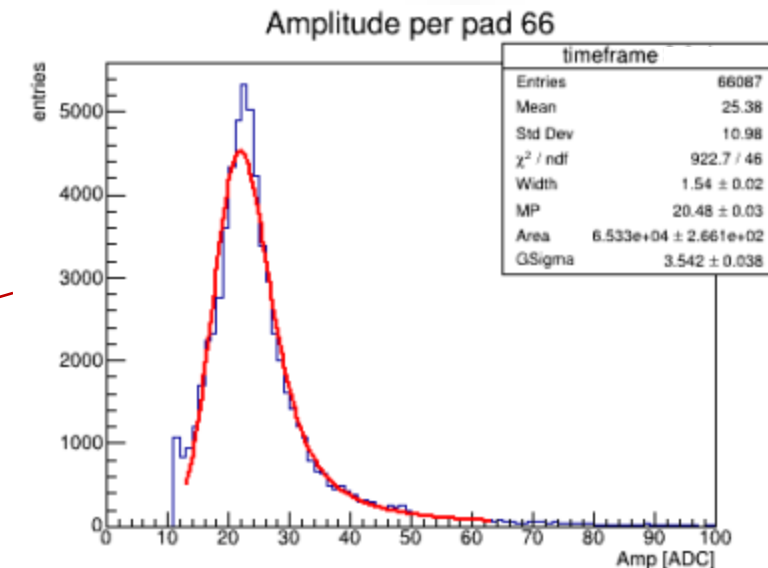
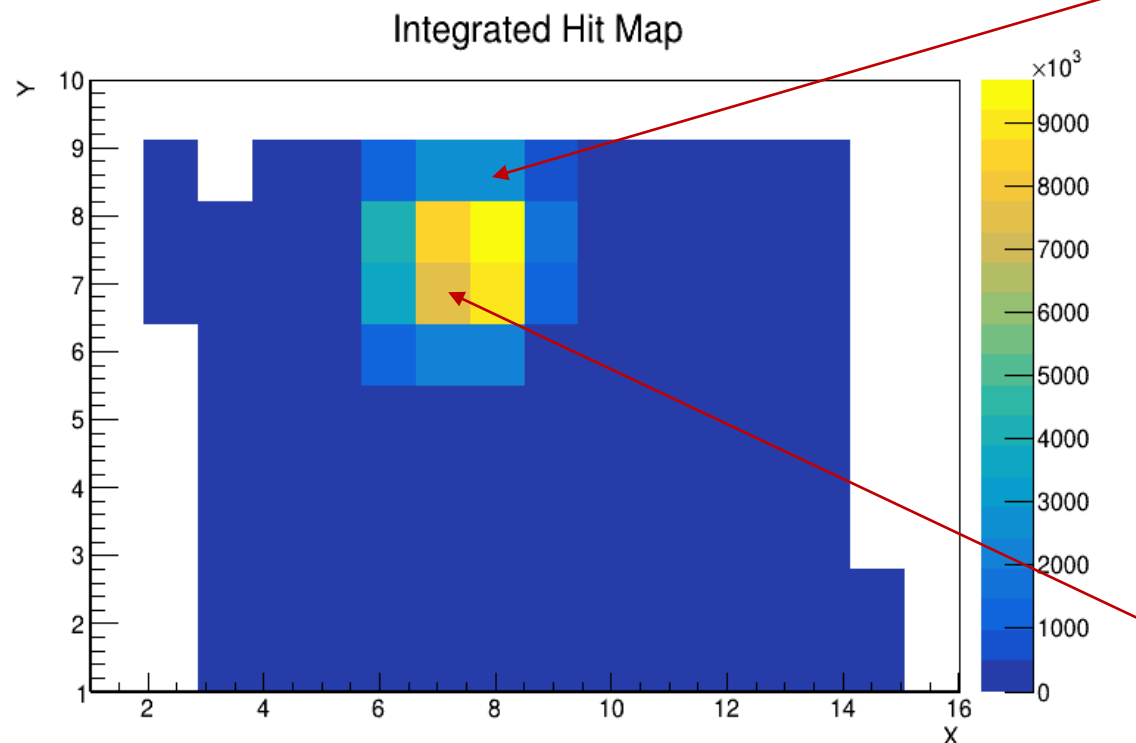
- for each pad a (Landau & Gauss) function was fitted to energy spectrum

Analysis conditions

- Kept all timeplanes
- Cut on amplitude < 900
- dead channels masked
- langaus fit [12-64] ADC

Data from run4484

- Beam on pads 42, 44, 62, 64
- Converted to channel number from sensor

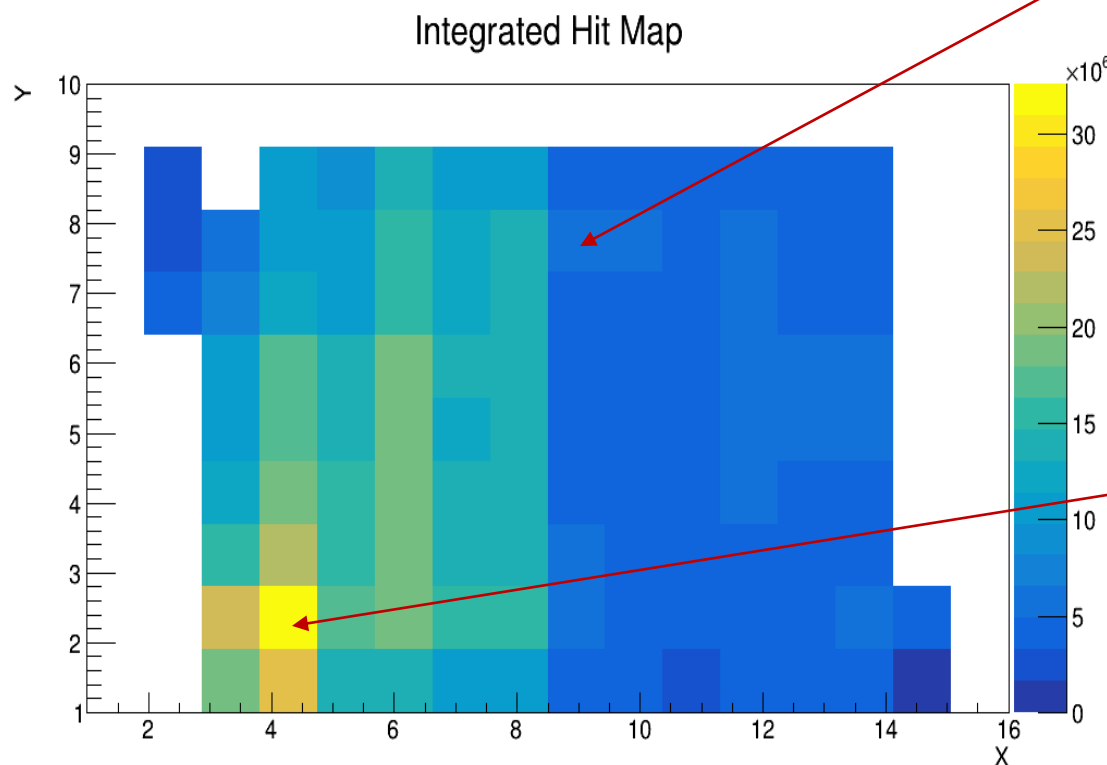


Simulations: MeV to ADC

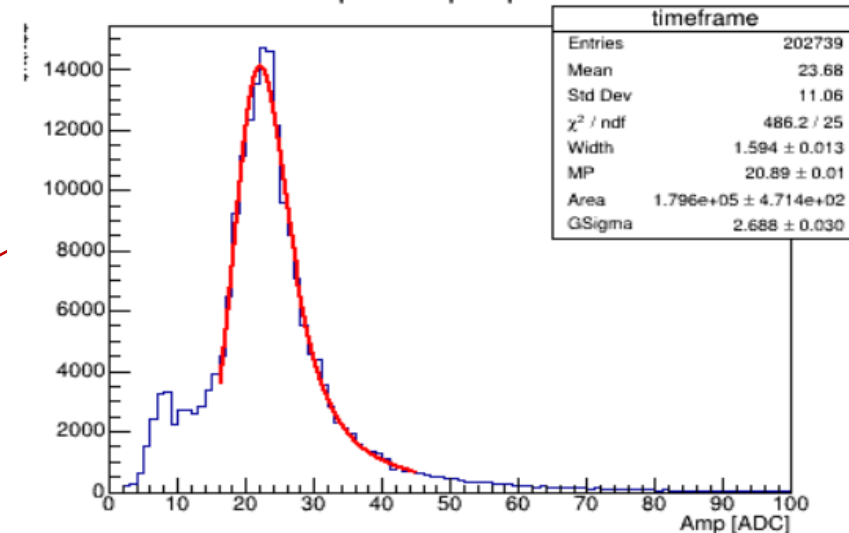
GaAs sensor – Anton1 , merged runs

Energy deposition:

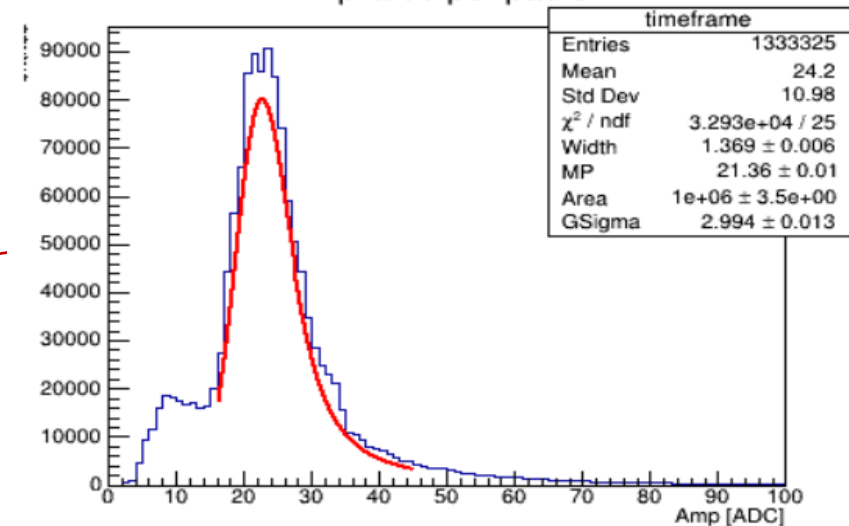
- merged all data from run4459 till run4491
- runs with Debug-data-ON or test runs not taken into account
- beam energy: 5 GeV
- greater number of runs and events for the left side of sensor



Amplitude per pad 82



Amplitude per pad 31



Simulations: MeV to ADC

GaAs sensor – Anton1 , merged runs

Energy deposition:

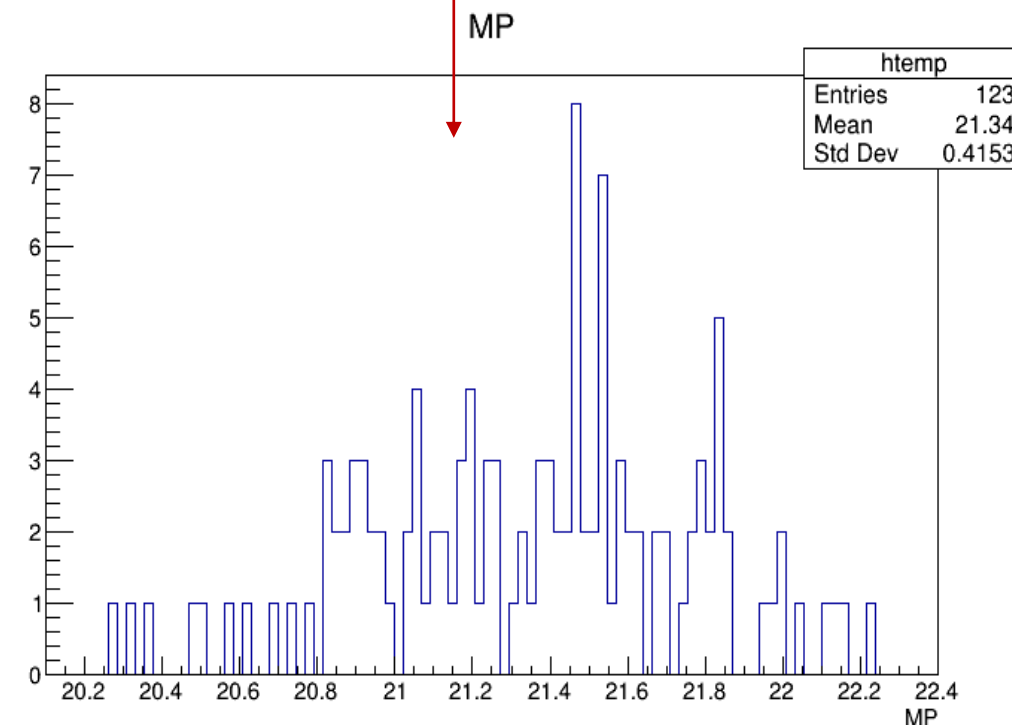
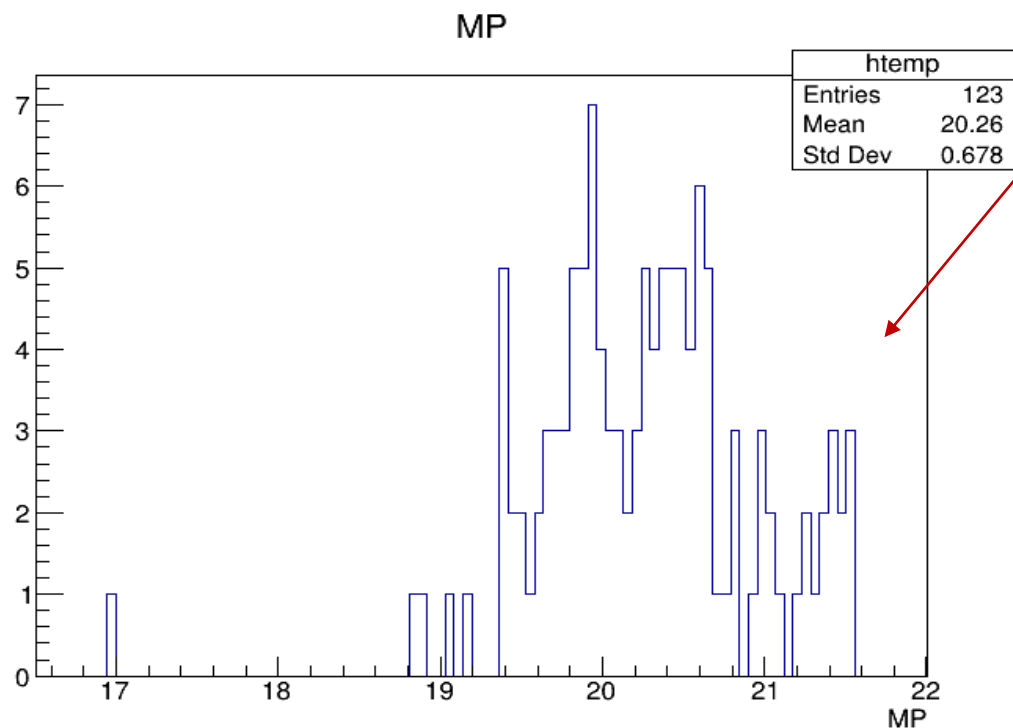
- 2 cases investigated: [run 4484] & [run 4459 – run 4491]
- fit with (Landau & Gauss) function all channels in [12-64] ADC range

Data from run4484

- Beam on pads 42, 44, 62, 64
- **MPV = 20.26 ± 0.68 [ADC]**

Data from merged runs

- **MPV = 21.34 ± 0.42 [ADC]**



Simulations vs Data

GaAs sensor – Anton1, run 4484

Energy deposition:

- Goal: compare simulations with data

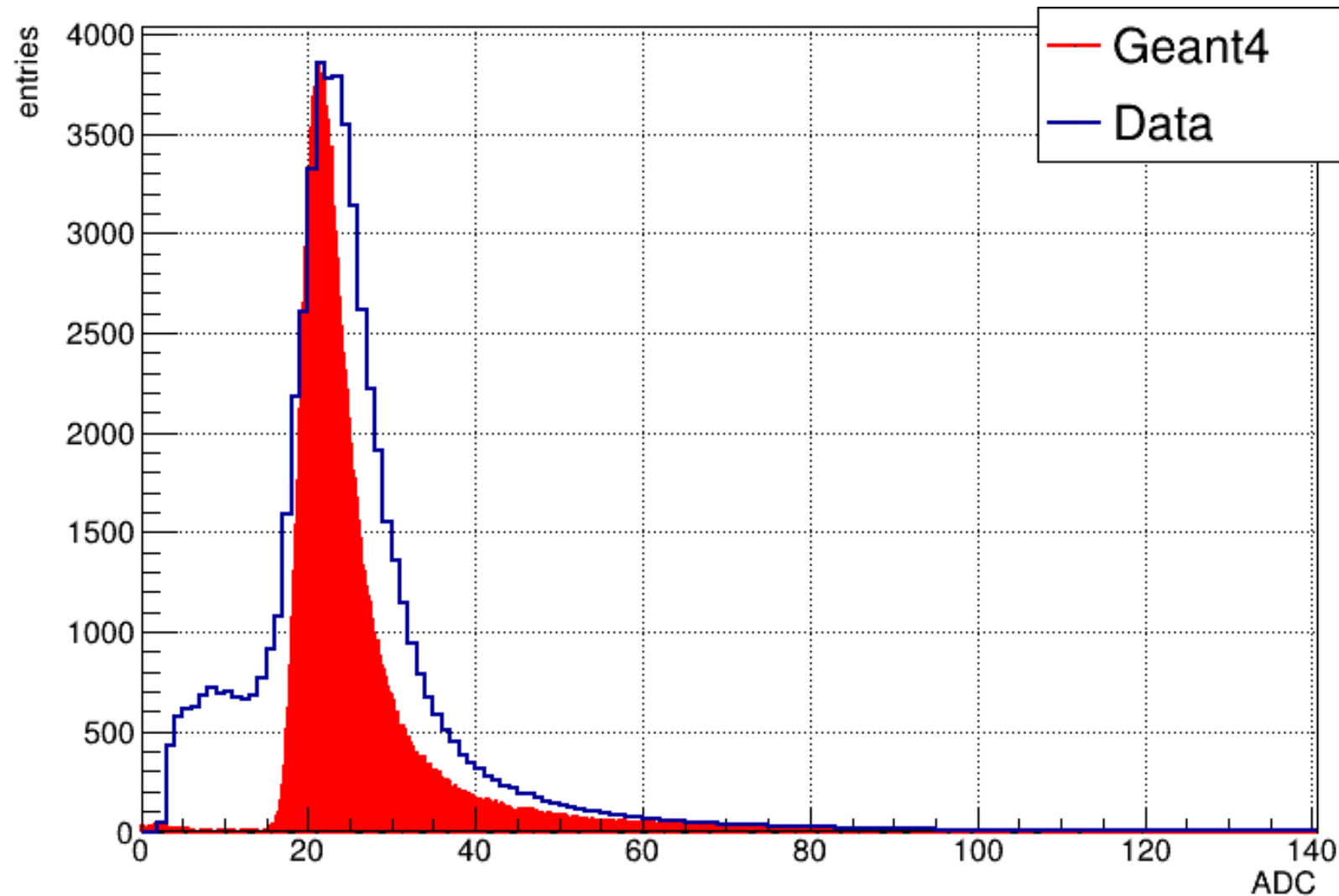
from data, run4484

- $1 \text{ MIP} = 20.26 \pm 0.68 \text{ [ADC]}$

from simulations

- $1 \text{ MIP} = 0.3569 \pm 0.12 \text{ MeV}$

- $1 \text{ MeV} = 56.77 \text{ ADC}$



Simulations: MeV to ADC

Si sensor – C75

Energy deposition:

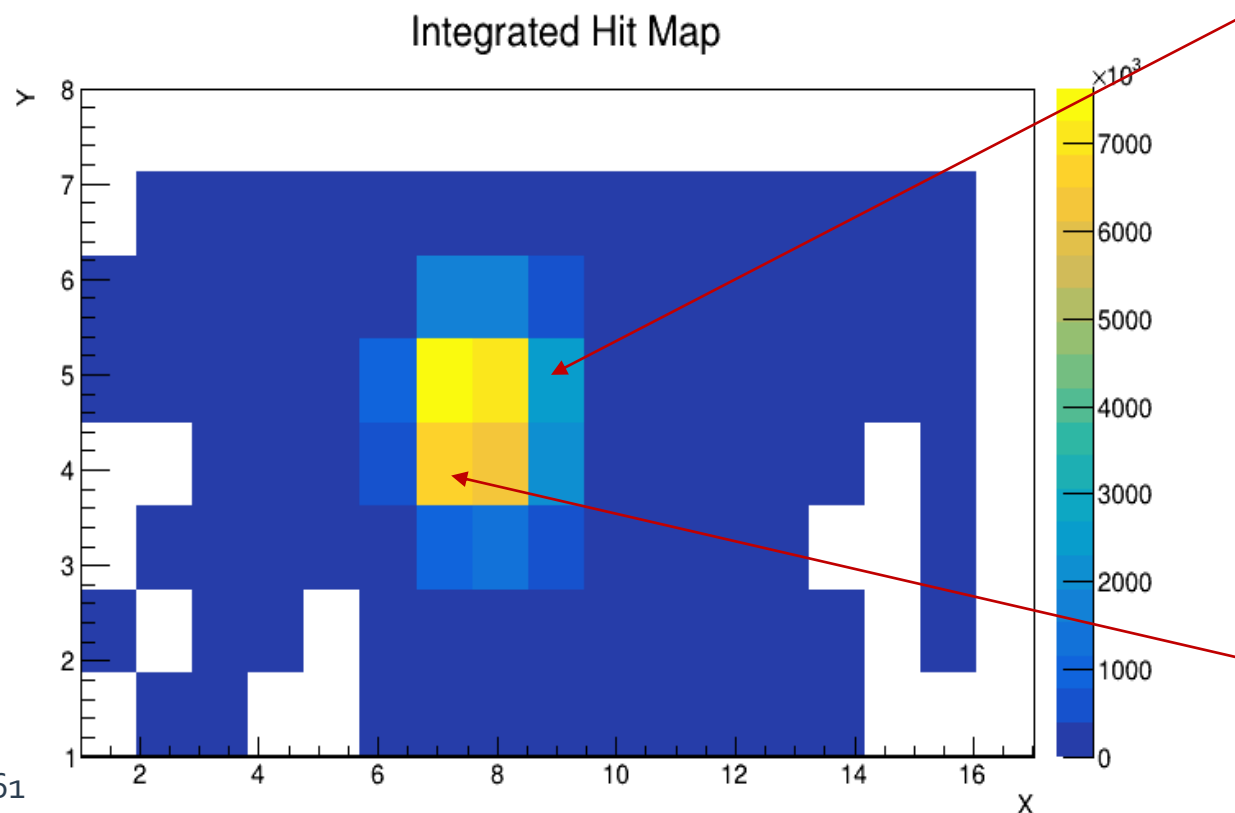
- for each pad a (Landau & Gauss) function was fitted to energy spectrum
- a lot of channels are dead or unresponsive

Analysis conditions

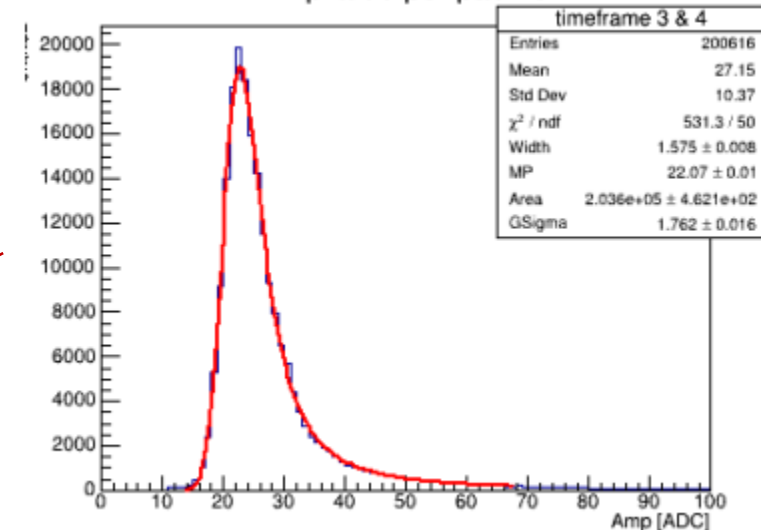
- Kept all timeplanes
- Cut on amplitude < 900
- dead channels masked
- langaus fit [12-64] ADC

Data from run4436

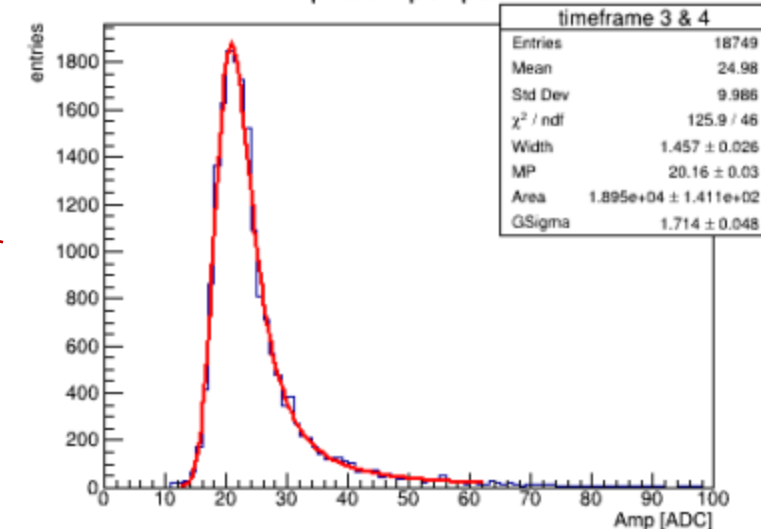
- Beam on pads 49, 51, 59, 61
- **Converted to channel number from sensor**



Amplitude per pad 49



Amplitude per pad 71



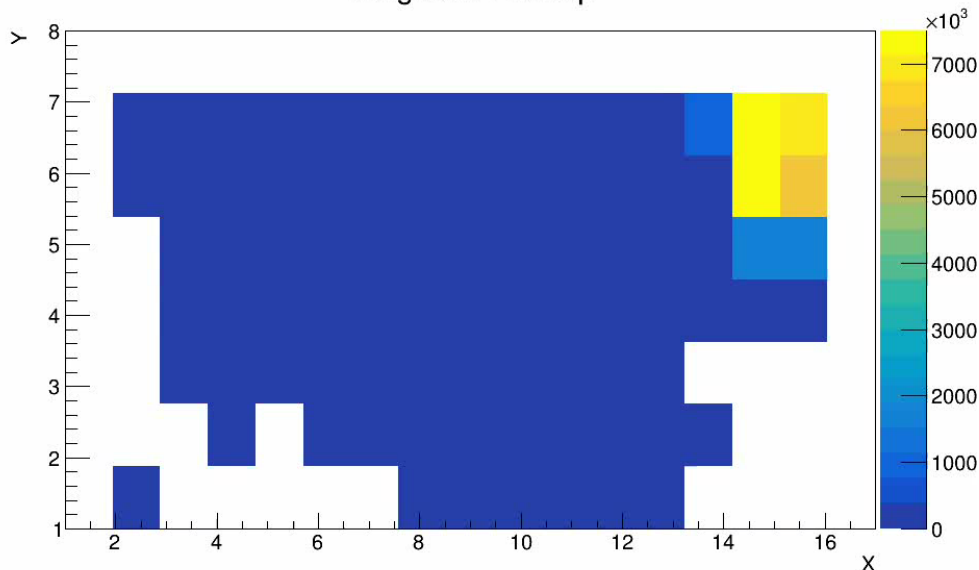
Simulations: MeV to ADC

Si sensor – C75

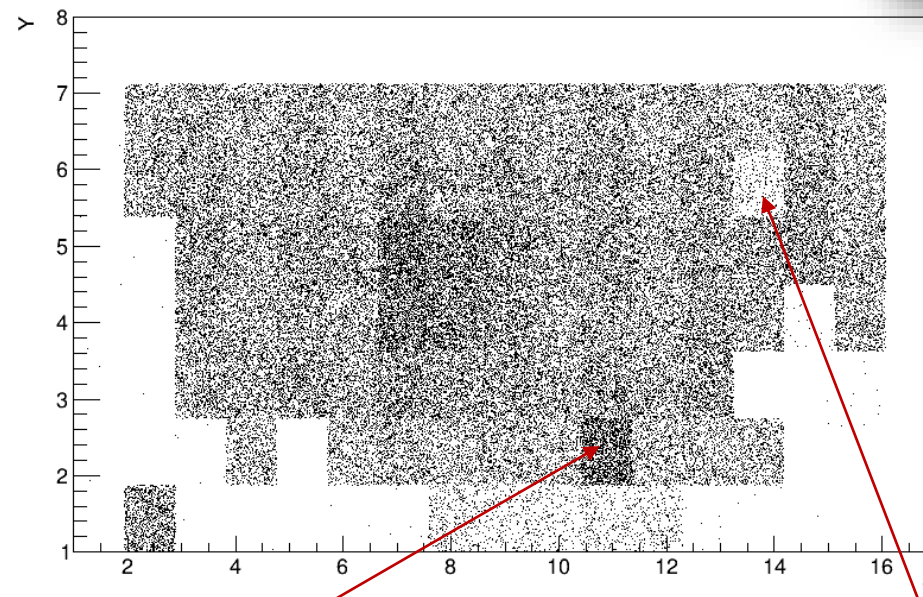
Energy deposition:

- merged all data from run4422 till run4447
- runs with Debug-data-ON or test runs not taken into account
- beam energy: 5 GeV
- many dead or unresponsive pads

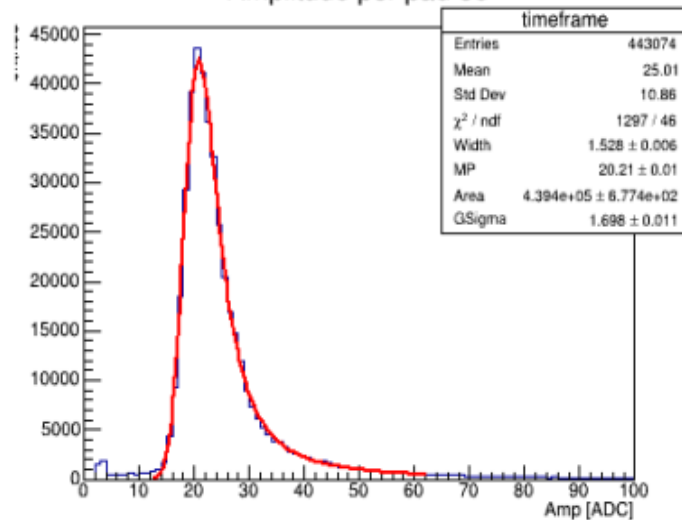
Integrated Hit Map



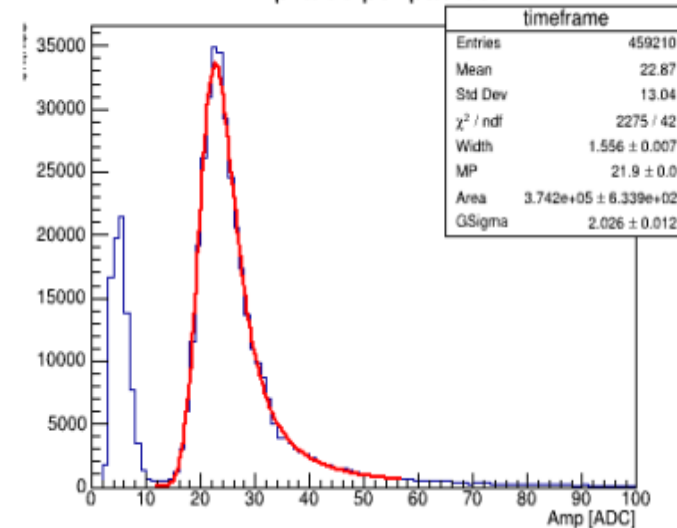
Integrated Hit Map



Amplitude per pad 86



Amplitude per pad 99

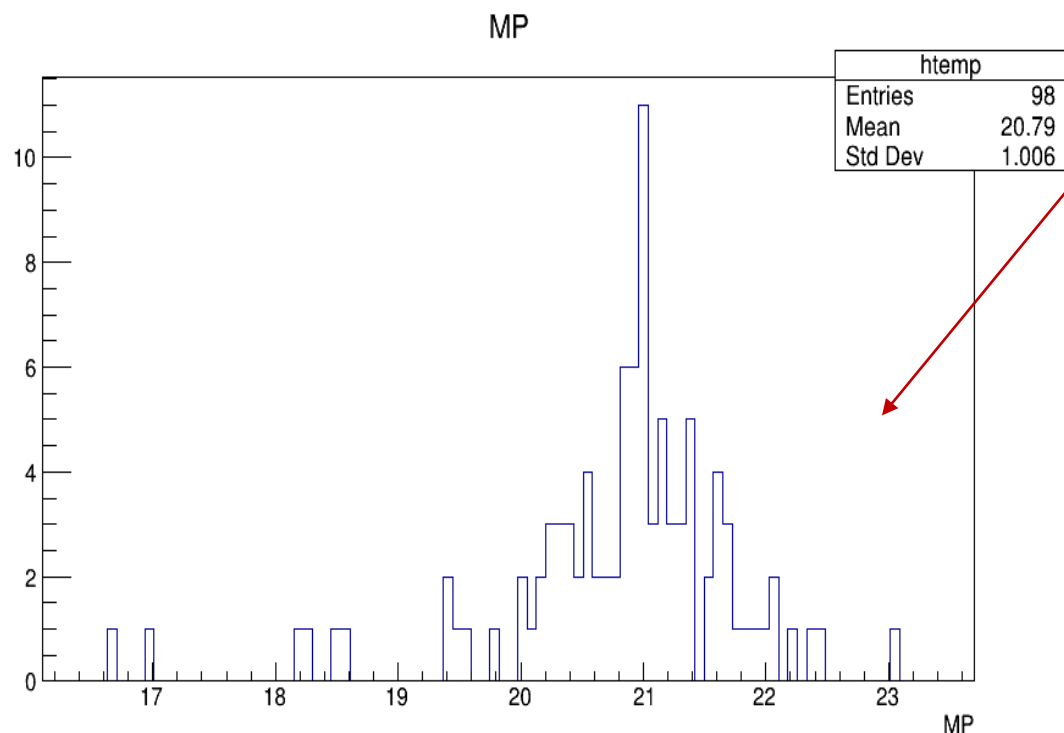


Simulations: MeV to ADC

Si sensor – C75

Energy deposition:

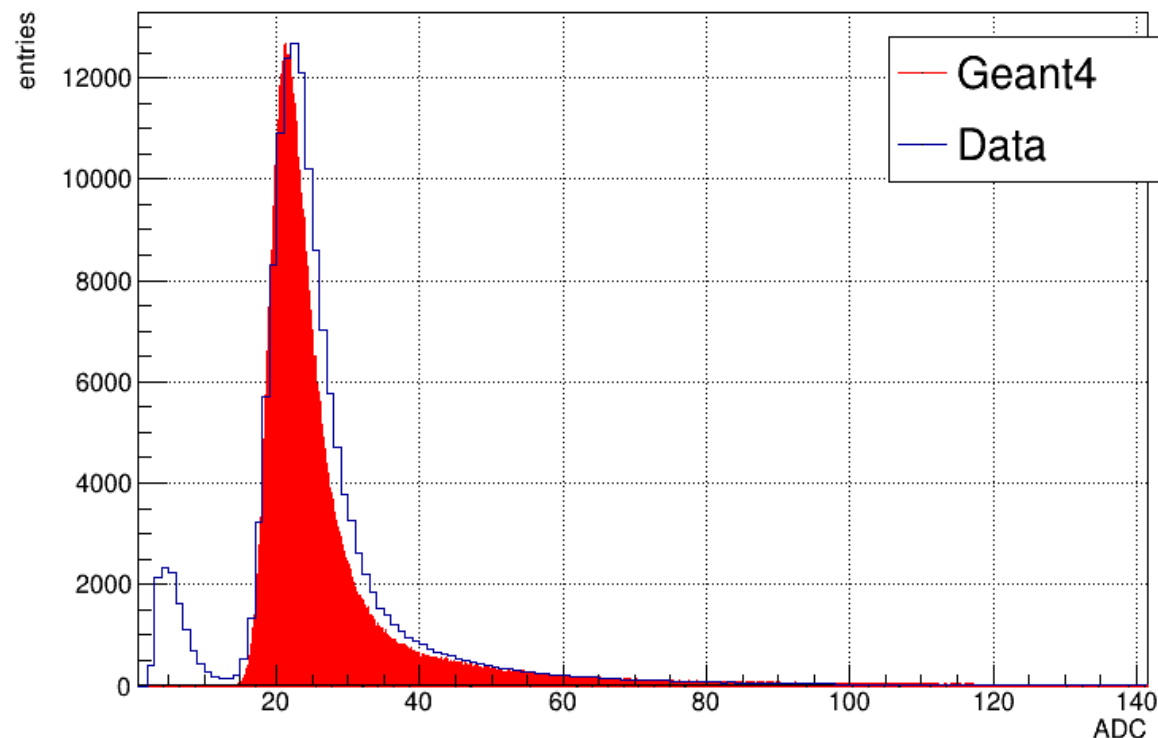
- 2 cases investigated: [run 4436] & [run 4422 – run 4447]
- fit with (Landau & Gauss) function all channels in [12-64] ADC range



Data from run4436

- Beam on pads 49, 51, 59, 61
- **MPV = 20.79 ± 1.07 [ADC]**

$$1 \text{ MeV} = 228.79 \text{ ADC}$$



Simulations vs Data

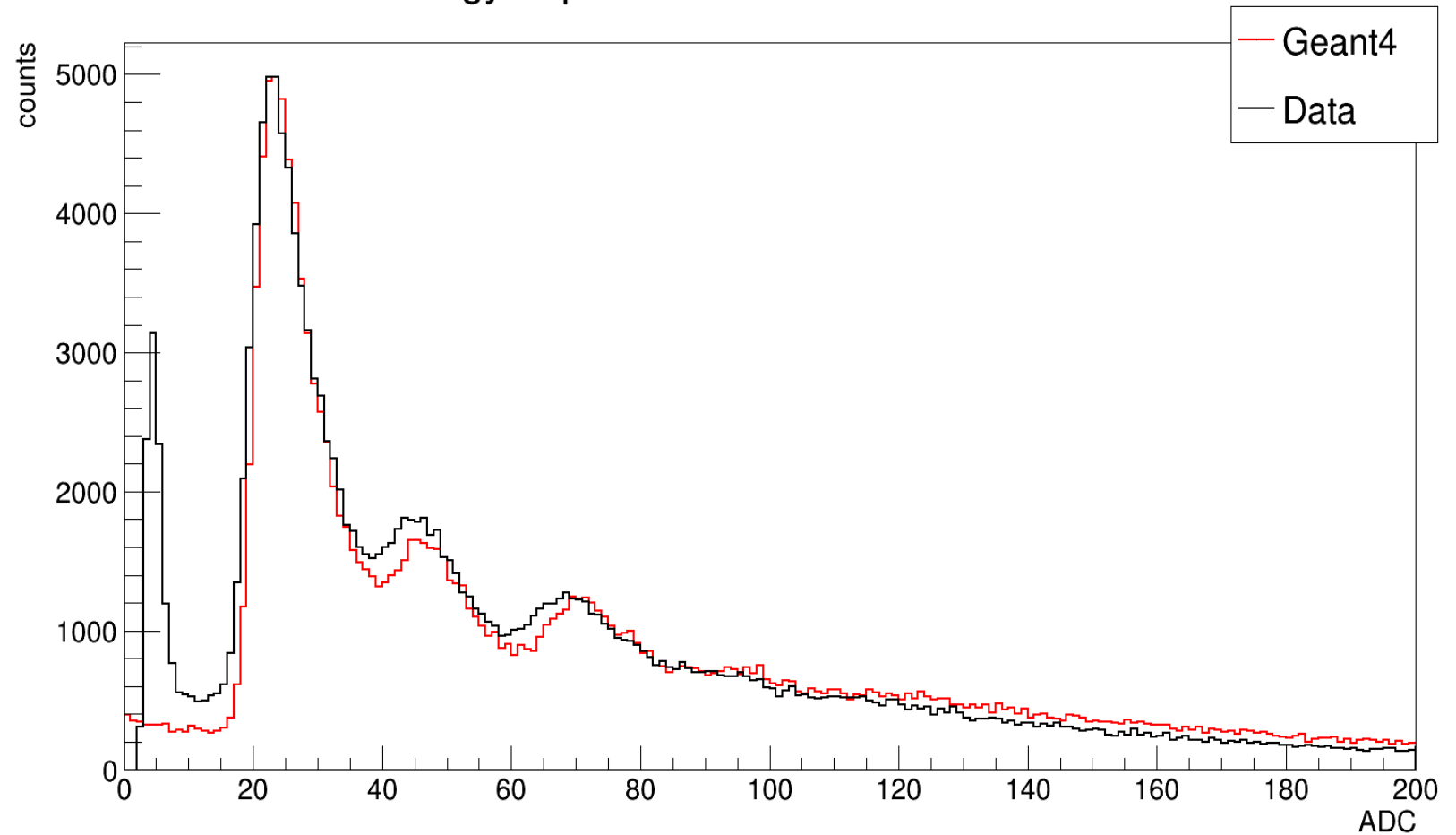
Si sensor – C74 + W

Energy deposition:

- experimental data: [run 4749]
- C74 sensor with 1 tungsten plate in front

Physics list used: FTFP_BERT_EMZ

Energy deposition for sensor with 1W

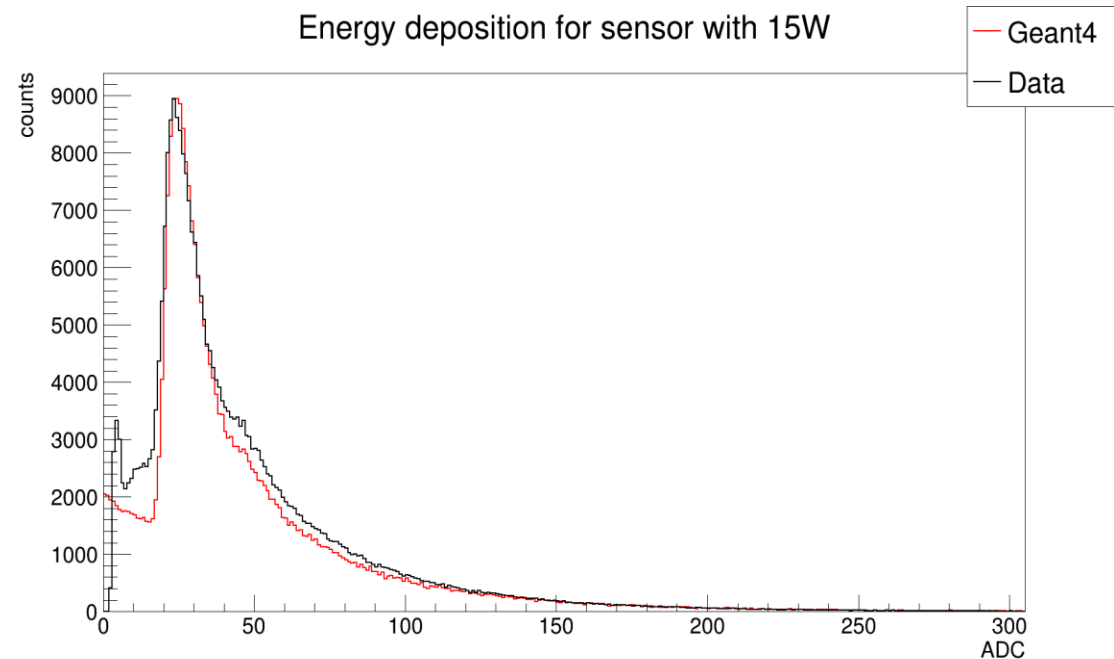
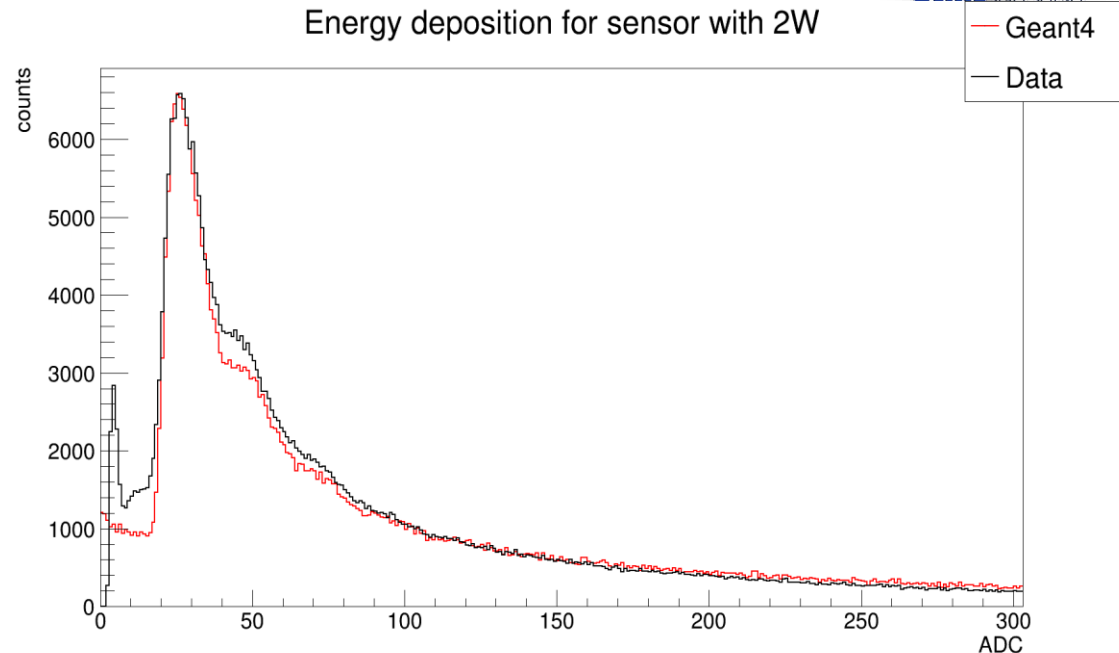
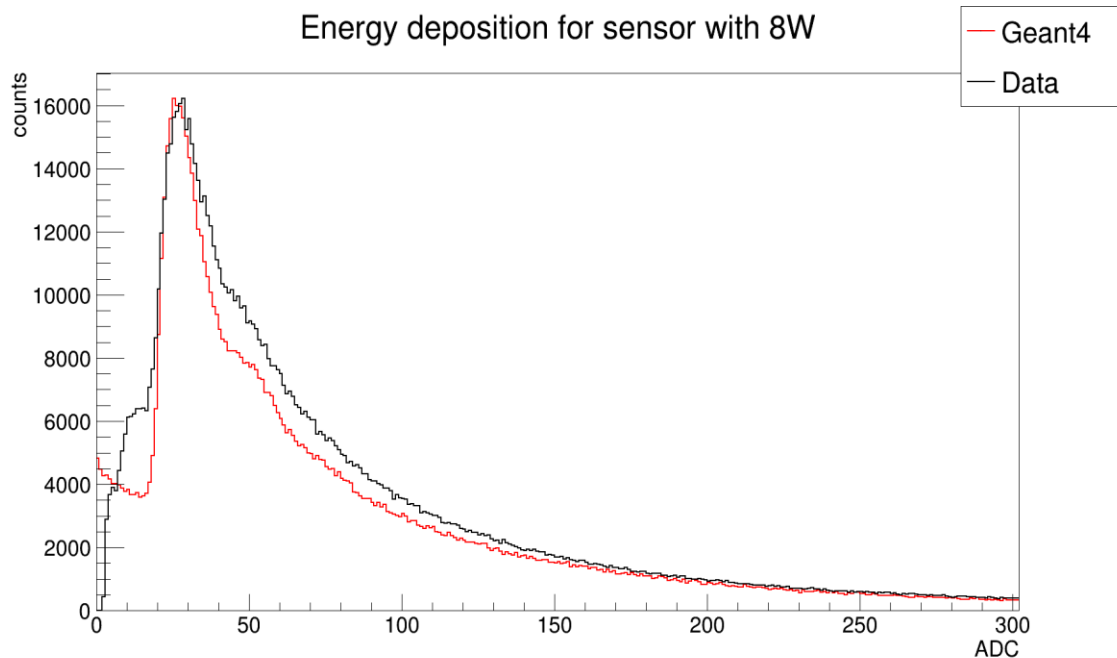


Simulations vs Data

Si sensor – C74 + nW

Energy deposition:

- C74 sensor with tungsten plates in front
- experimental data: [run 4748] – 2W
[run 4742] – 8W
[run 4735] – 15W



Physics list used: FTFP_BERT_EMZ

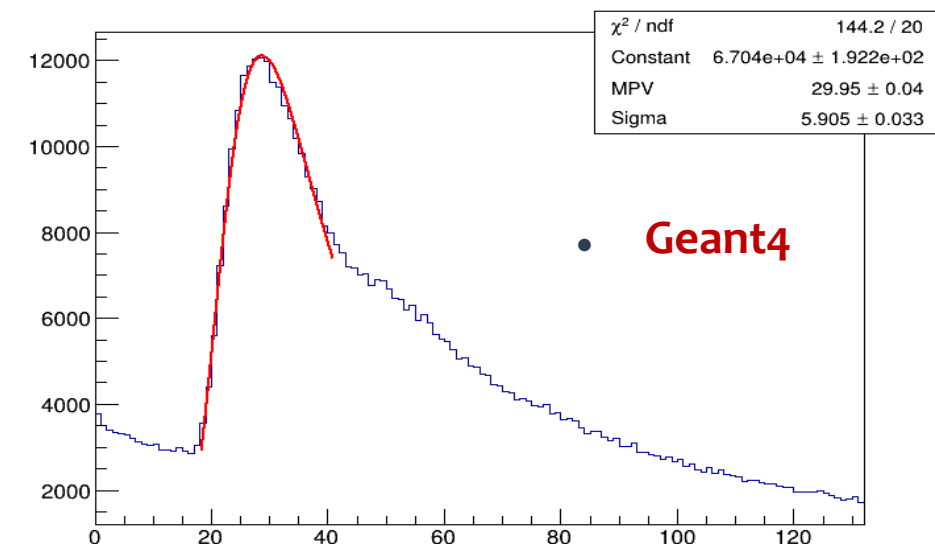
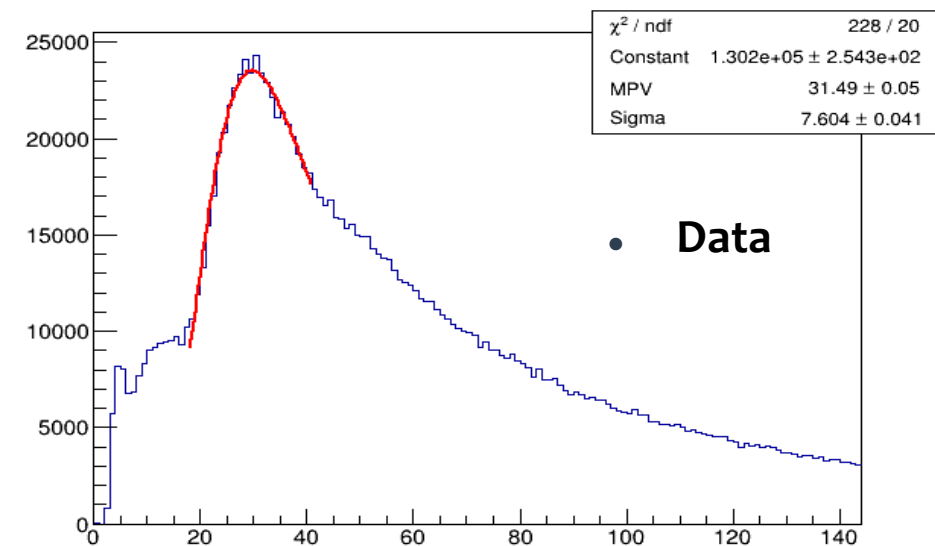
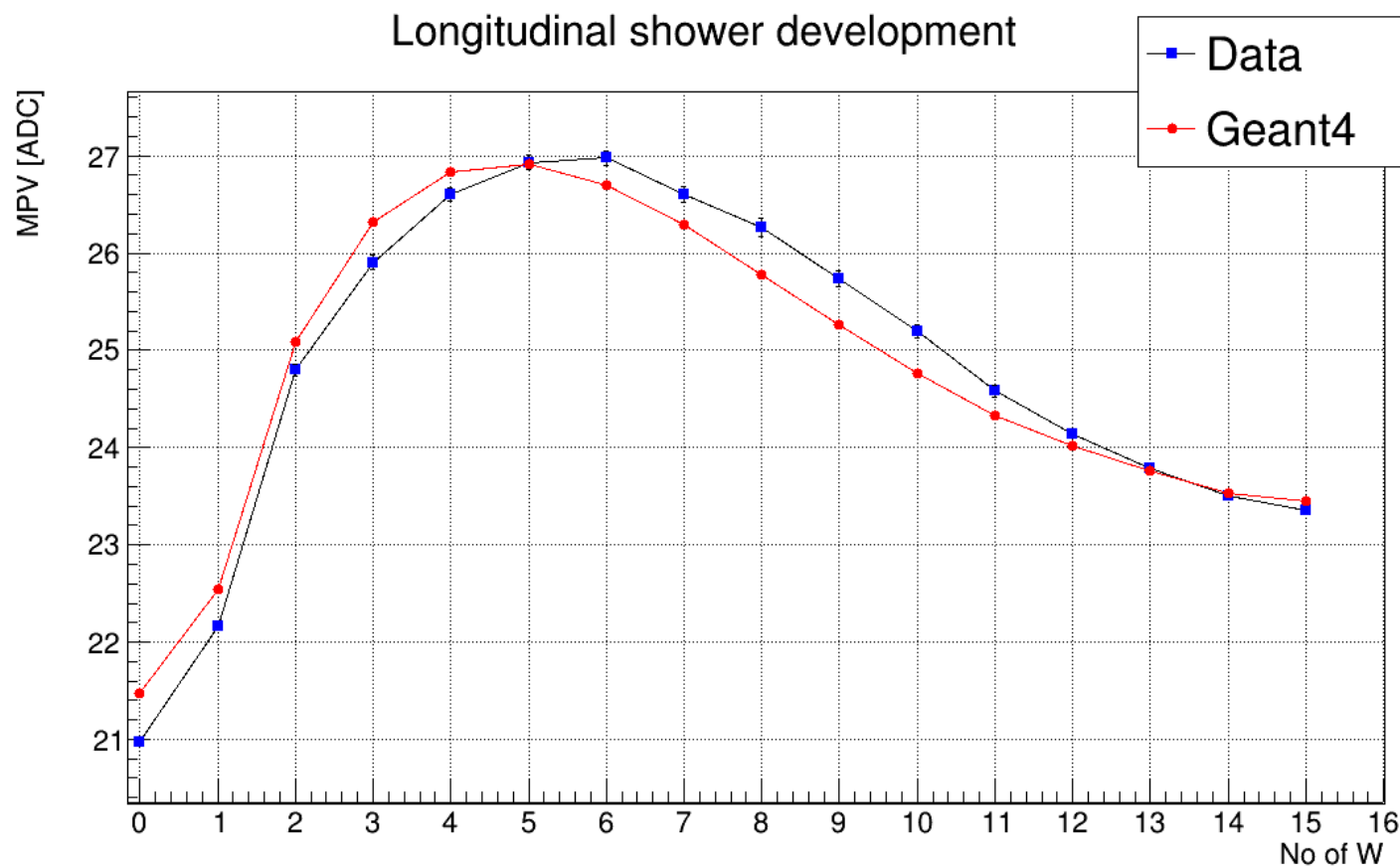
Simulations vs Data

Si sensor – C74 + nW

Energy deposition:

- C74 sensor with tungsten plates in front
- experimental data: [run 4748 - run 4735]

Physics list used:
FTFP_BERT_EMZ



Analysis - done and *to be done*

- evaluate each pad energy deposition
- fit the energy deposition histograms to get the MPV
- evaluate MPV for different setup configurations
- compare simulation results with data from test beam
- find the longitudinal shower distribution for different configurations (e.g. 1 to 15 W plates in front of sensor)
- *move beam position on x-y directions to compare with different runs*
- *add digitization of the signal*
- *telescope is only 1.5 cm height (compared to 4.5 cm Si or 5 cm GaAs) -> is this an explanation of empty events?*

Thank you!